

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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- **Outstanding Combination of dc Precision and AC Performance:**

Unity-Gain Bandwidth . . . 15 MHz Typ

V_n 3.3 nV/ $\sqrt{\text{Hz}}$ at $f = 10$ Hz Typ,
2.5 nV/ $\sqrt{\text{Hz}}$ at $f = 1$ kHz Typ

V_{IO} 25 μV Max

A_{VD} 45 V/ μV Typ With $R_L = 2$ k Ω ,
19 V/ μV Typ With $R_L = 600$ Ω

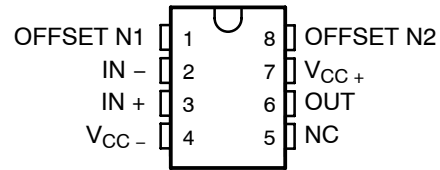
- Available in Standard-Pinout Small-Outline Package
- Output Features Saturation Recovery Circuitry
- Macromodels and Statistical information

description

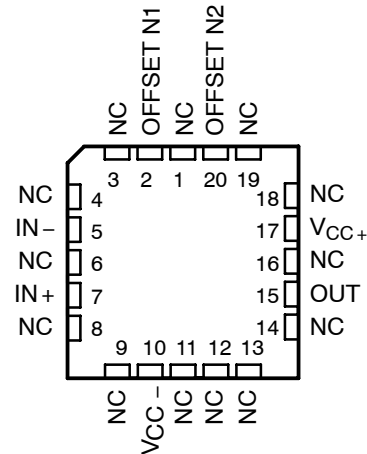
The TLE20x7 and TLE20x7A contain innovative circuit design expertise and high-quality process control techniques to produce a level of ac performance and dc precision previously unavailable in single operational amplifiers. Manufactured using Texas Instruments state-of-the-art Excalibur process, these devices allow upgrades to systems that use lower-precision devices.

In the area of dc precision, the TLE20x7 and TLE20x7A offer maximum offset voltages of 100 μV and 25 μV , respectively, common-mode rejection ratio of 131 dB (typ), supply voltage rejection ratio of 144 dB (typ), and dc gain of 45 V/ μV (typ).

D, JG, OR P PACKAGE
(TOP VIEW)



FK PACKAGE
(TOP VIEW)



AVAILABLE OPTIONS

T_A	V_{IOmax} AT 25°C	PACKAGED DEVICES				CHIP FORM [‡] (Y)
		SMALL OUTLINE [†] (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	25 μV	TLE2027ACD TLE2037ACD	— —	— —	TLE2027ACP TLE2037ACP	TLE2027Y TLE2037Y
	100 μV	TLE2027CD TLE2037CD	— —	— —	TLE2027CP TLE2037CP	TLE2027Y TLE2037Y
–40°C to 105°C	25 μV	TLE2027AID TLE2037AID	— —	— —	TLE2027AIP TLE2037AIP	—
	100 μV	TLE2027ID TLE2037ID	— —	— —	TLE2027IP TLE2037IP	—
–55°C to 125°C	25 μV	TLE2027AMD TLE2037AMD	TLE2027AMFK TLE2037AMFK	TLE2027AMJG TLE2037AMJG	TLE2027AMP TLE2037AMP	—
	100 μV	TLE2027MD TLE2037MD	TLE2027MFK TLE2037MFK	TLE2027MJG TLE2037MJG	TLE2027MP TLE2037MP	—

[†] The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2027ACDR).

[‡] Chip forms are tested at 25°C only.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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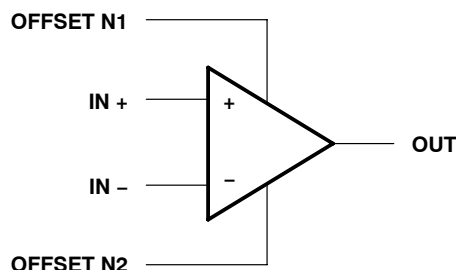
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description (continued)

The ac performance of the TLE2027 and TLE2037 is highlighted by a typical unity-gain bandwidth specification of 15 MHz, 55° of phase margin, and noise voltage specifications of 3.3 nV/ $\sqrt{\text{Hz}}$ and 2.5 nV/ $\sqrt{\text{Hz}}$ at frequencies of 10 Hz and 1 kHz respectively. The TLE2037 and TLE2037A have been decompensated for faster slew rate ($-7.5 \text{ V}/\mu\text{s}$, typical) and wider bandwidth (50 MHz). To ensure stability, the TLE2037 and TLE2037A should be operated with a closed-loop gain of 5 or greater.

Both the TLE20x7 and TLE20x7A are available in a wide variety of packages, including the industry-standard 8-pin small-outline version for high-density system applications. The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from -40°C to 105°C . The M-suffix devices are characterized for operation over the full military temperature range of -55°C to 125°C .

symbol

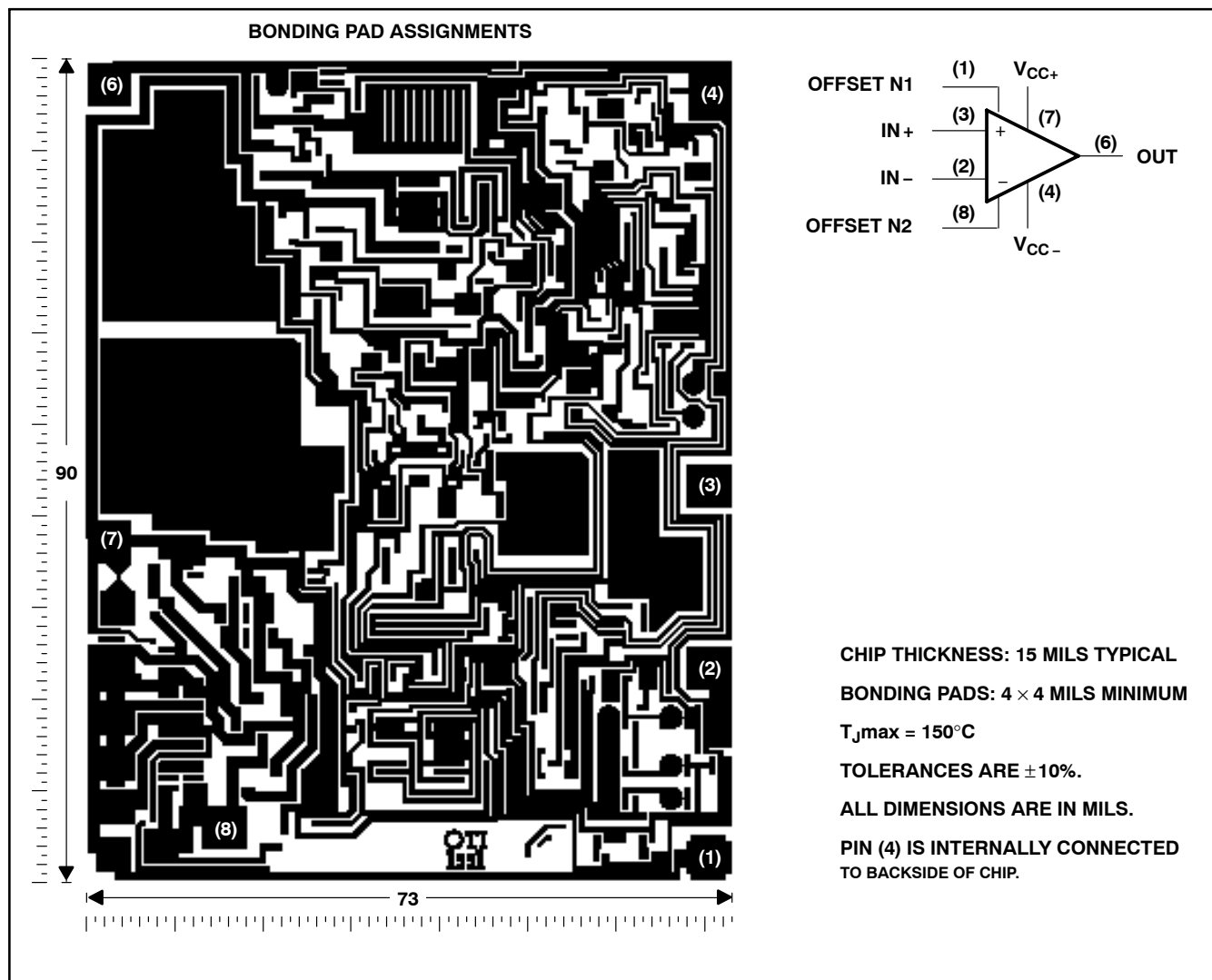


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TLE202xY chip information

This chip, when properly assembled, displays characteristics similar to the TLE202xC. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. The chip may be mounted with conductive epoxy or a gold-silicon preform.



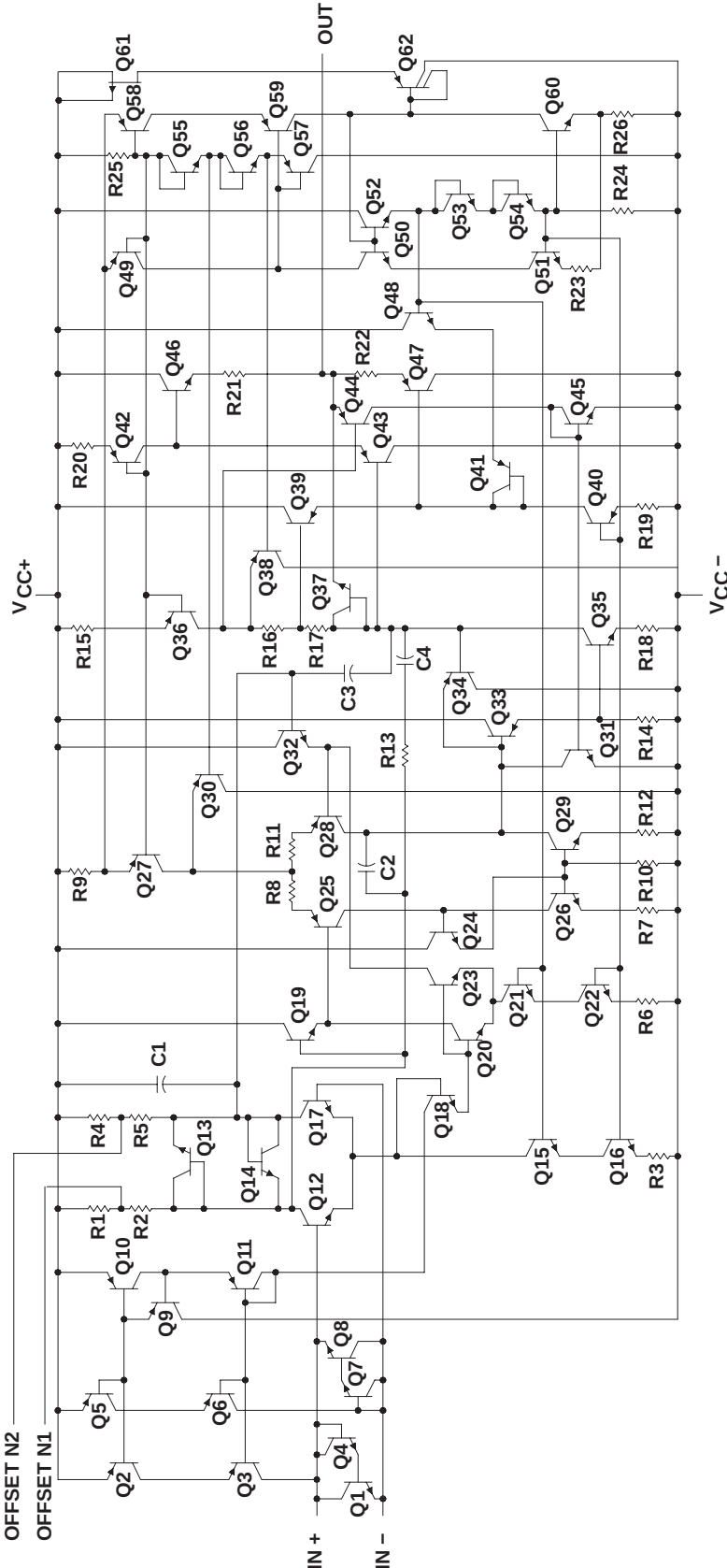
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equivalent schematic



ACTUAL DEVICE COMPONENT COUNT		
COMPONENT	TLE2027	TLE2037
Transistors	61	61
Resistors	26	26
epiFET	1	1
Capacitors	4	4

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	19 V
Supply voltage, V_{CC-}	– 19 V
Differential input voltage, V_{ID} (see Note 2)	± 1.2 V
Input voltage range, V_I (any input)	$V_{CC\pm}$
Input current, I_I (each Input)	± 1 mA
Output current, I_O	± 50 mA
Total current into V_{CC+}	50 mA
Total current out of V_{CC-}	50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	– 40°C to 105°C
M suffix	– 55°C to 125°C
Storage temperature range, T_{stg}	– 65°C to 150°C
Case temperature for 60 seconds, T_C : FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or P package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG package	300°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
2. Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows if a differential input voltage in excess of approximately ± 1.2 V is applied between the inputs unless some limiting resistance is used.
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 105^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	261 mW	145 mW
FK	1375 mW	11.0 mW/°C	880 mW	495 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	378 mW	210 mW
P	1000 mW	8.0 mW/°C	640 mW	360 mW	200 mW

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC\pm}$		± 4	± 19	± 4	± 19	± 4	± 19	V
Common-mode input voltage, V_{IC}	$T_A = 25^\circ\text{C}$	– 11	11	– 11	11	– 11	11	V
	$T_A = \text{Full range}^\ddagger$	– 10.5	10.5	– 10.4	10.4	– 10.2	10.2	
Operating free-air temperature, T_A		0	70	– 40	105	– 55	125	°C

[‡] Full range is 0°C to 70°C for C-suffix devices, – 40°C to 105°C for I-suffix devices, and – 55°C to 125°C for M-suffix devices.

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TLE20x7C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE20x7C			TLE20x7AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	20	100		10	25		μV
		Full range		145			70		
α_{VIO} Temperature coefficient of input offset voltage		Full range	0.4	1		0.2	1		$\mu V/^\circ C$
Input offset voltage long-term drift (see Note 4)		25°C	0.006	1		0.006	1		$\mu V/mo$
I_{IO} Input offset current		25°C	6	90		6	90		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	15	90		15	90		nA
		Full range		150			150		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–11 to 11	–13 to 13		–11 to 11	–13 to 13		V
		Full range	–10.5 to 10.5			–10.5 to 10.5			
V_{OM+} Maximum positive peak output voltage swing	$R_L = 600 \Omega$	25°C	10.5	12.9		10.5	12.9		V
		Full range	10			10			
	$R_L = 2 k\Omega$	25°C	12	13.2		12	13.2		
		Full range	11			11			
V_{OM-} Maximum negative peak output voltage swing	$R_L = 600 \Omega$	25°C	–10.5	–13		–10.5	–13		V
		Full range	–10			–10			
	$R_L = 2 k\Omega$	25°C	–12	–13.5		–12	–13.5		
		Full range	–11			–11			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 11$ V, $R_L = 2 k\Omega$	25°C	5	45		10	45		V/ μV
	$V_O = \pm 10$ V, $R_L = 2 k\Omega$	Full range	2			4			
	$V_O = \pm 10$ V, $R_L = 1 k\Omega$	25°C	3.5	38		8	38		
		Full range	1			2.5			
	$V_O = \pm 10$ V, $R_L = 600 \Omega$	25°C	2	19		5	19		
		Full range	0.5			2			
C_i Input capacitance		25°C	8			8			pF
z_o Open-loop output impedance	$I_O = 0$	25°C	50			50			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	100	131		117	131		dB
		Full range	98			114			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 4$ V to ± 18 V, $R_S = 50 \Omega$	25°C	94	144		110	144		dB
	$V_{CC\pm} = \pm 4$ V to ± 18 V, $R_S = 50 \Omega$	Full range	92			106			
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	3.8	5.3		3.8	5.3		mA
		Full range		5.6			5.6		

† Full range is 0°C to 70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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TLE20x7C operating characteristics at specified free-air temperature, $V_{CC} \pm = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS		TLE20x7C			TLE20x7AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	TLE2027	1.7	2.8		1.7	2.8		V/ μs
			TLE2037	6	7.5		6	7.5		
		$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, $T_A = 0^\circ\text{C}$ to 70°C , See Figure 1	TLE2027	1.2			1.2			
			TLE2037	5			5			
V_n	Equivalent input noise voltage (see Figure 2)	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		3.3	8		3.3	4.5	nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		2.5	4.5		2.5	3.8		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz}$ to 10 Hz		50	250		50	130	nV	
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		10	25		10	25	pA/ $\sqrt{\text{Hz}}$	
		$f = 1\text{ kHz}$		0.8	1.8		0.8	1.8		
THD	Total harmonic distortion	$V_O = +10\text{ V}$, $A_{VD} = 1$, See Note 5	TLE2027	< 0.002%			< 0.002%			
		$V_O = +10\text{ V}$, $A_{VD} = 5$, See Note 5	TLE2037	< 0.002%			< 0.002%			
B_1	Unity-gain bandwidth (see Figure 3)	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	TLE2027	9 ⁽⁶⁾	13		9 ⁽⁶⁾	13	MHz	
GBW	Gain bandwidth product	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	TLE2037	35	50		35	50		
B_{OM}	Maximum output-swing bandwidth	$R_L = 2\text{ k}\Omega$	TLE2027	30			30		kHz	
			TLE2037	80			80			
ϕ_m	Phase margin at unity gain (see Figure 3)	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	TLE2027	55°			55°			
			TLE2037	50°			50°			

NOTE 5: Measured distortion of the source used in the analysis was 0.002%.

NOTE 6: This parameter is not production tested

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TLE20x7I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A [†]	TLE20x7I			TLE20x7AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω	25°C	20 100		10 25		μV		
			Full range	180		105				
α _{VIO}	Temperature coefficient of input offset voltage		Full range	0.4 1		0.2 1		μV/°C		
	Input offset voltage long-term drift (see Note 4)		25°C	0.006 1		0.006 1		μV/mo		
I _{IO}	Input offset current		25°C	6 90		6 90		nA		
			Full range	150		150				
I _{IB}	Input bias current		25°C	15 90		15 90		nA		
			Full range	150		150				
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω	25°C	–11 –13 to to 11 13		–11 –13 to to 11 13		V		
			Full range	–10.4 to 10.4		–10.4 to 10.4				
V _{OM} +	Maximum positive peak output voltage swing	R _L = 600 Ω	25°C	10.5 12.9		10.5 12.9		V		
			Full range	10		10				
		R _L = 2 kΩ	25°C	12 13.2		12 13.2				
			Full range	11		11				
V _{OM} –	Maximum negative peak output voltage swing	R _L = 600 Ω	25°C	–10.5 –13		–10.5 –13		V		
			Full range	–10		–10				
		R _L = 2 kΩ	25°C	–12 –13.5		–12 –13.5				
			Full range	–11		–11				
A _{VD}	Large-signal differential voltage amplification	V _O = ±11 V, R _L = 2 kΩ	25°C	5 45		10 45		V/μV		
		V _O = ±10 V, R _L = 2 kΩ	Full range	2		3.5				
		V _O = ±10 V, R _L = 1 kΩ	25°C	3.5 38		8 38				
			Full range	1		2.2				
		V _O = ±10 V, R _L = 600 Ω	25°C	2 19		5 19				
			Full range	0.5		1.1				
C _i	Input capacitance		25°C	8		8		pF		
z _o	Open-loop output impedance	I _O = 0	25°C	50		50		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω	25°C	100 131		117 131		dB		
			Full range	96		113				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±4 V to ±18 V, R _S = 50 Ω	25°C	94 144		110 144		dB		
		V _{CC±} = ±4 V to ±18 V, R _S = 50 Ω	Full range	90		105				
I _{CC}	Supply current	V _O = 0, No load	25°C	3.8 5.3		3.8 5.3		mA		
			Full range	5.6		5.6				

† Full range is –40°C to 105°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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TLE20x7I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise specified)

PARAMETER	TEST CONDITIONS		TLE20x7I			TLE20x7AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 2 kΩ, C _L = 100 pF, See Figure 1	TLE2027	1.7	2.8		1.7	2.8	V/μs
		TLE2037	6	7.5		6	7.5		
		R _L = 2 kΩ, C _L = 100 pF, T _A = −40°C to 85°C, See Figure 1	TLE2027	1.1			1.1		
		TLE2037	4.7			4.7			
V _n	Equivalent input noise voltage (see Figure 2)	R _S = 20 Ω, f = 10 Hz		3.3	8		3.3	4.5	nV/√Hz
		R _S = 20 Ω, f = 1 kHz		2.5	4.5		2.5	3.8	
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		50	250		50	130	nV
I _n	Equivalent input noise current	f = 10 Hz		10	25		10	25	pA/√Hz
		f = 1 kHz		0.8	1.8		0.8	1.8	
THD	Total harmonic distortion	V _O = +10 V, A _{VD} = 1, See Note 5	TLE2027	< 0.002%			< 0.002%		
		V _O = +10 V, A _{VD} = 5, See Note 5	TLE2037	< 0.002%			< 0.002%		
B ₁	Unity-gain bandwidth (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	9 ⁽⁶⁾	13		9 ⁽⁶⁾	13	MHz
GBW	Gain bandwidth product	R _L = 2 kΩ, C _L = 100 pF	TLE2037	35	50		35	50	
B _{OM}	Maximum output-swing bandwidth	R _L = 2 kΩ	TLE2027	30			30		kHz
			TLE2037	80			80		
ϕ _m	Phase margin at unity gain (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	55°			55°		
			TLE2037	50°			50°		

NOTE 5: Measured distortion of the source used in the analysis was 0.002%.

NOTE 6: This parameter is not production tested.

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TLE20x7M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A [†]	TLE20x7M			TLE20x7AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω	25°C	20	100	10	25	μV		
			Full range	200			105			
α _{VIO}	Temperature coefficient of input offset voltage		Full range	0.4	1*	0.2	1*	μV/°C		
	Input offset voltage long-term drift (see Note 4)		25°C	0.006	1*	0.006	1*	μV/mo		
I _{IO}	Input offset current		25°C	6	90	6	90	nA		
			Full range	150			150			
I _{IB}	Input bias current		25°C	15	90	15	90	nA		
			Full range	150			150			
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω	25°C	–11 to 11	–13 to 13	–11 to 11	–13 to 13	V		
			Full range	–10.3 to 10.3		–10.4 to 10.4				
V _{OM} +	Maximum positive peak output voltage swing	R _L = 600 Ω	25°C	10.5	12.9	10.5	12.9	V		
			Full range	10			10			
		R _L = 2 kΩ	25°C	12	13.2	12	13.2			
			Full range	11			11			
V _{OM} –	Maximum negative peak output voltage swing	R _L = 600 Ω	25°C	–10.5	–13	–10.5	–13	V		
			Full range	–10			–10			
		R _L = 2 kΩ	25°C	–12	–13.5	–12	–13.5			
			Full range	–11			–11			
A _{VD}	Large-signal differential voltage amplification	V _O = ±11 V, R _L = 2 kΩ	25°C	5	45	10	45	V/μV		
		V _O = ±10 V, R _L = 2 kΩ	Full range	2.5			3.5			
		V _O = ±10 V, R _L = 1 kΩ	25°C	3.5	38	8	38			
		Full range	1.8			2.2				
		V _O = ±10 V, R _L = 600 Ω	25°C	2	19	5	19			
C _i	Input capacitance		25°C	8			8		pF	
z _o	Open-loop output impedance	I _O = 0	25°C	50			50		Ω	
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω	25°C	100	131	117	131	dB		
			Full range	96			113			
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±4 V to ±18 V, R _S = 50 Ω	25°C	94	144	110	144	dB		
		V _{CC±} = ±4 V to ±18 V, R _S = 50 Ω	Full range	90			105			
I _{CC}	Supply current	V _O = 0, No load	25°C	3.8	5.3	3.8	5.3	mA		
			Full range	5.6			5.6			

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† Full range is –55°C to 125°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ C$ extrapolated to $T_A = 25^\circ C$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y
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TLE20x7M operating characteristics at specified free-air temperature, $V_{CC} \pm = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS		TLE20x7M			TLE20x7AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 2 kΩ, C _L = 100 pF, See Figure 1	TLE2027	1.7	2.8		1.7	2.8		V/μs
			TLE2037	6*	7.5		6*	7.5		
		R _L = 2 kΩ, C _L = 100 pF, T _A = −55°C to 125°C, See Figure 1	TLE2027	1			1			
			TLE2037	4.4*			4.4*			
V _n	Equivalent input noise voltage (see Figure 2)	R _S = 20 Ω, f = 10 Hz		3.3	8*		3.3	8*	nV/√Hz	
		R _S = 20 Ω, f = 1 kHz		2.5	4*		2.5	4*		
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		225	375*		225	375*	nV	
I _n	Equivalent input noise current	f = 10 Hz		25			25		pA/√Hz	
		f = 1 kHz		2.5			2.5			
THD	Total harmonic distortion	V _O = +10 V, A _{VD} = 1, See Note 5	TLE2027	< 0.002%			< 0.002%			
		V _O = +10 V, A _{VD} = 5, See Note 5	TLE2037	< 0.002%			< 0.002%			
B ₁	Unity-gain bandwidth (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	7*	13		9*	13	MHz	
			TLE2037	35	50		35	50		
B _{OM}	Maximum output-swing bandwidth	R _L = 2 kΩ	TLE2027	30			30		kHz	
			TLE2037	80			80			
ϕ _m	Phase margin at unity gain (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	55°			55°			
			TLE2037	50°			50°			

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

NOTE 5: Measured distortion of the source used in the analysis was 0.002%.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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TLE20x7Y electrical characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE20x7Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$		20		μV
Input offset voltage long-term drift (see Note 4)			0.006		$\mu\text{V}/\text{mo}$
I_{IO} Input offset current			6		nA
I_{IB} Input bias current			15		nA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$		-13 to 13		V
V_{OM+} Maximum positive peak output voltage swing	$R_L = 600\ \Omega$		12.9		V
	$R_L = 2\ \text{k}\Omega$		13.2		
V_{OM-} Maximum negative peak output voltage swing	$R_L = 600\ \Omega$		-13		V
	$R_L = 2\ \text{k}\Omega$		-13.5		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 11\text{ V}$, $R_L = 2\ \text{k}\Omega$		45		V/ μV
	$V_O = \pm 10\text{ V}$, $R_L = 1\ \text{k}\Omega$		38		
	$V_O = \pm 10\text{ V}$, $R_L = 600\ \Omega$		19		
C_i Input capacitance			8		pF
z_o Open-loop output impedance	$I_O = 0$		50		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\text{min}}$, $R_S = 50\ \Omega$		131		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 4\text{ V to } \pm 18\text{ V}$, $R_S = 50\ \Omega$		144		dB
I_{CC} Supply current	$V_O = 0$, No load		3.8		mA

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y
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TLE20x7Y operating characteristics at specified free-air temperature, $V_{CC} \pm = \pm 15\text{ V}$

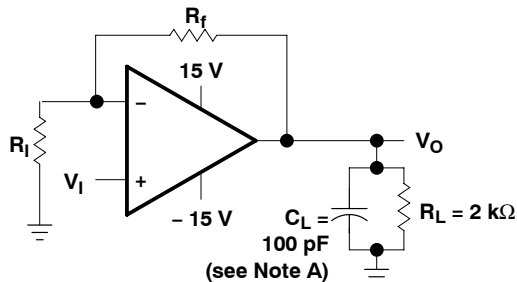
PARAMETER		TEST CONDITIONS		TLE20x7Y			UNIT
				MIN	TYP	MAX	
SR	Slew rate at unity gain	R _L = 2 kΩ, C _L = 100 pF, See Figure 1	TLE2027	2.8			V/μs
			TLE2037	7.5			
V _n	Equivalent input noise voltage (see Figure 2)	R _S = 20 Ω, f = 10 Hz		3.3			nV/√Hz
		R _S = 20 Ω, f = 1 kHz		2.5			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		50			nV
I _n	Equivalent input noise current	f = 10 Hz		10			pA/√Hz
		f = 1 kHz		0.8			
THD	Total harmonic distortion	V _O = +10 V, A _{VD} = 1, See Note 5	TLE2027	<0.002%			
		V _O = +10 V, A _{VD} = 5, See Note 5	TLE2037	<0.002%			
B ₁	Unity-gain bandwidth (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	13			MHz
			TLE2037	50			
B _{OM}	Maximum output-swing bandwidth	R _L = 2 kΩ	TLE2027	30			kHz
			TLE2037	80			
φ _m	Phase margin at unity gain (see Figure 3)	R _L = 2 kΩ, C _L = 100 pF	TLE2027	55°			
			TLE2037	50°			

NOTE 5: Measured distortion of the source used in the analysis was 0.002%.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes fixture capacitance.

Figure 1. Slew-Rate Test Circuit

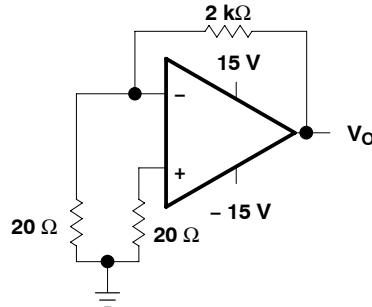
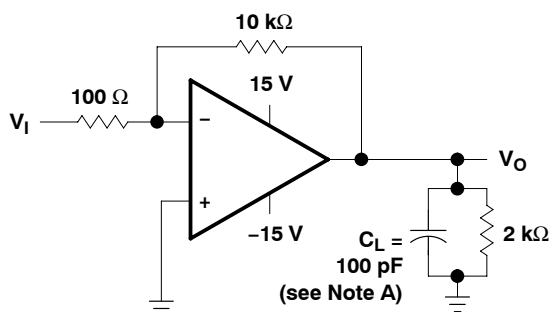
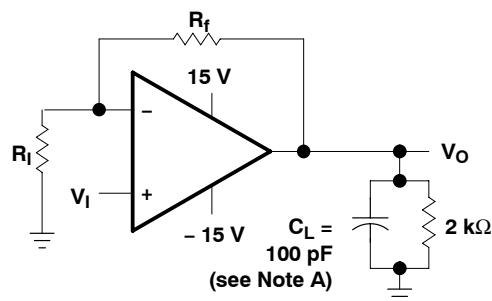


Figure 2. Noise-Voltage Test Circuit



NOTE A: C_L includes fixture capacitance.

Figure 3. Unity-Gain Bandwidth and Phase-Margin Test Circuit (TLE2027 Only)



NOTES: A. C_L includes fixture capacitance.
B. For the TLE2037 and TLE2037A, A_{VD} must be ≥ 5 .

Figure 4. Small-Signal Pulse-Response Test Circuit

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

initial estimates of parameter distributions

In the ongoing program of improving data sheets and supplying more information to our customers, Texas Instruments has added an estimate of not only the typical values but also the spread around these values. These are in the form of distribution bars that show the 95% (upper) points and the 5% (lower) points from the characterization of the initial wafer lots of this new device type (see Figure 5). The distribution bars are shown at the points where data was actually collected. The 95% and 5% points are used instead of ± 3 sigma since some of the distributions are not true Gaussian distributions.

The number of units tested and the number of different wafer lots used are on all of the graphs where distribution bars are shown. As noted in Figure 5, there were a total of 835 units from two wafer lots. In this case, there is a good estimate for the within-lot variability and a possibly poor estimate of the lot-to-lot variability. This is always the case on newly released products since there can only be data available from a few wafer lots.

The distribution bars are not intended to replace the minimum and maximum limits in the electrical tables. Each distribution bar represents 90% of the total units tested at a specific temperature. While 10% of the units tested fell outside any given distribution bar, this should not be interpreted to mean that the same individual devices fell outside every distribution bar.

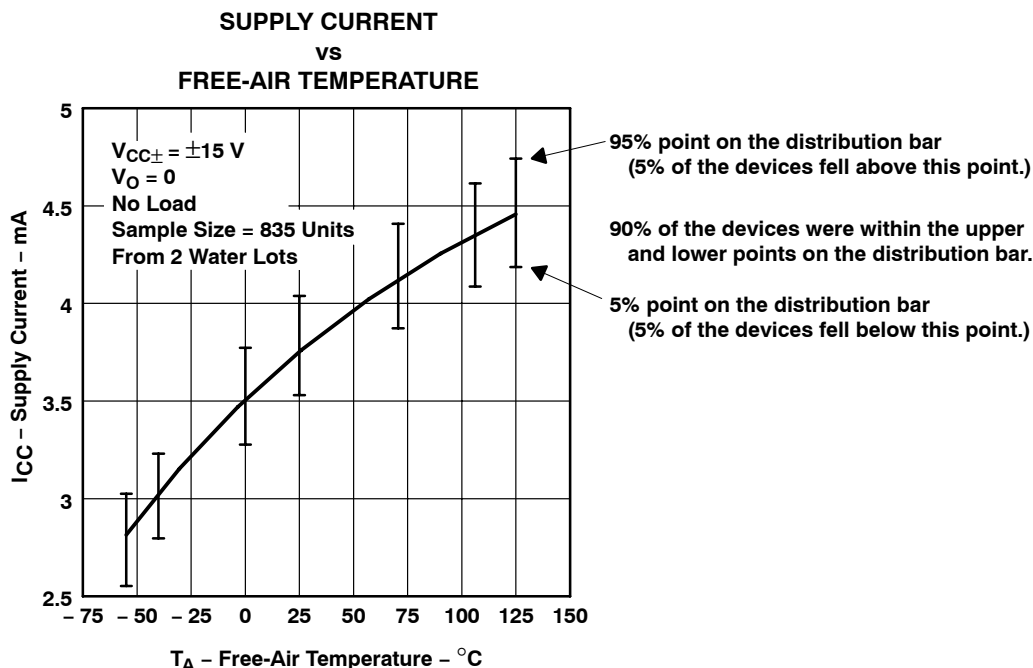


Figure 5. Sample Graph With Distribution Bars

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

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TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	6, 7
ΔV_{IO}	Input offset voltage change	vs Time after power on	8, 9
I_{IO}	Input offset current	vs Free-air temperature	10
I_{IB}	Input bias current	vs Free-air temperature	11
		vs Common-mode input voltage	12
I_I	Input current	vs Differential input voltage	13
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	14, 15
V_{OM}	Maximum (positive/negative) peak output voltage	vs Load resistance	16, 17
		vs Free-air temperature	18, 19
A_{VD}	Large-signal differential voltage amplification	vs Supply voltage	20
		vs Load resistance	21
		vs Frequency	22 – 25
		vs Free-air temperature	26
z_o	Output impedance	vs Frequency	27
CMRR	Common-mode rejection ratio	vs Frequency	28
k_{SVR}	Supply-voltage rejection ratio	vs Frequency	29
I_{OS}	Short-circuit output current	vs Supply voltage	30, 31
		vs Elapsed time	32, 33
		vs Free-air temperature	34, 35
I_{CC}	Supply current	vs Supply voltage	36
		vs Free-air temperature	37
	Voltage-follower pulse response	Small signal	38, 40
		Large signal	39, 41
V_n	Equivalent input noise voltage	vs Frequency	42
	Noise voltage (referred to input)	Over 10-second interval	43
B_1	Unity-gain bandwidth	vs Supply voltage	44
		vs Load capacitance	45
	Gain bandwidth product	vs Supply voltage	46
		vs Load capacitance	47
SR	Slew rate	vs Free-air temperature	48, 49
ϕ_m	Phase margin	vs Supply voltage	50, 51
		vs Load capacitance	52, 53
		vs Free-air temperature	54, 55
	Phase shift	vs Frequency	22 – 25

TYPICAL CHARACTERISTICS

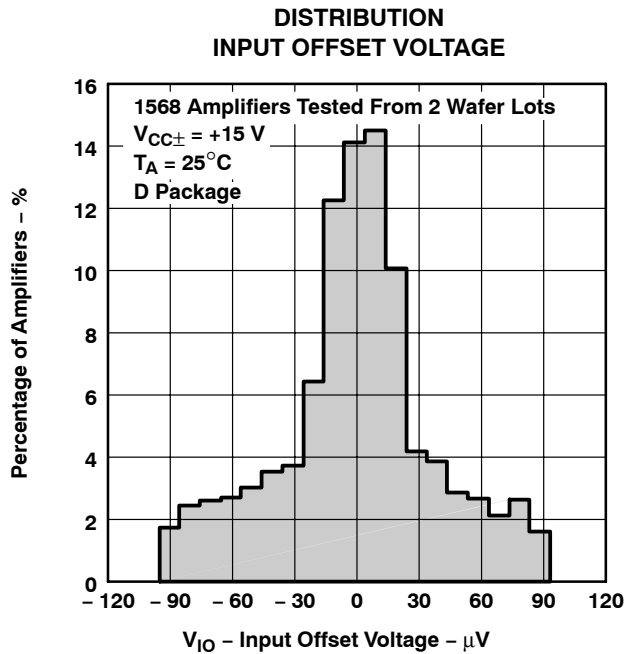


Figure 6

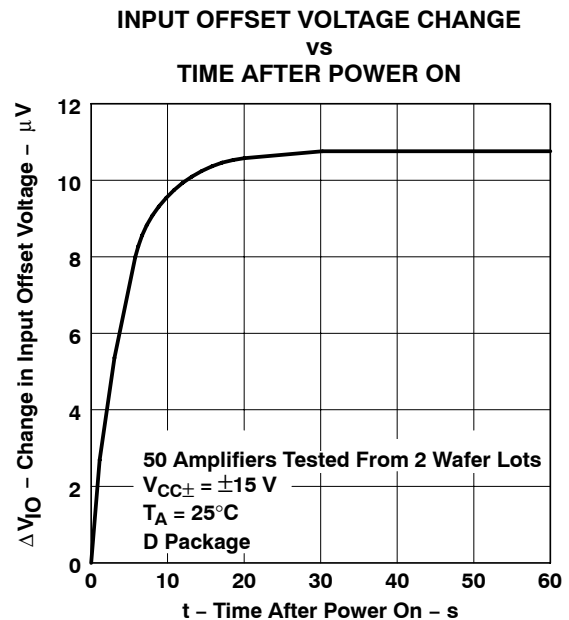


Figure 7

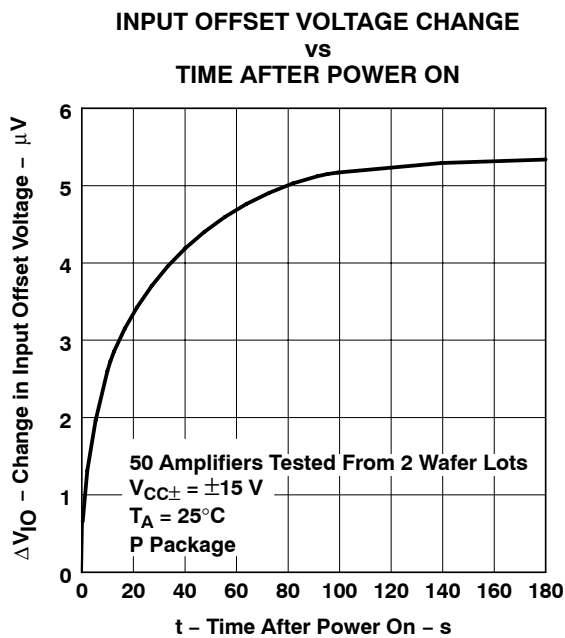


Figure 8

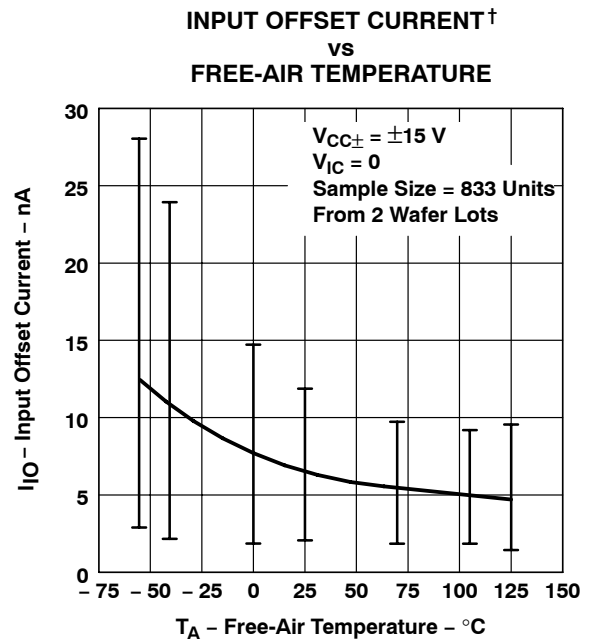


Figure 9

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

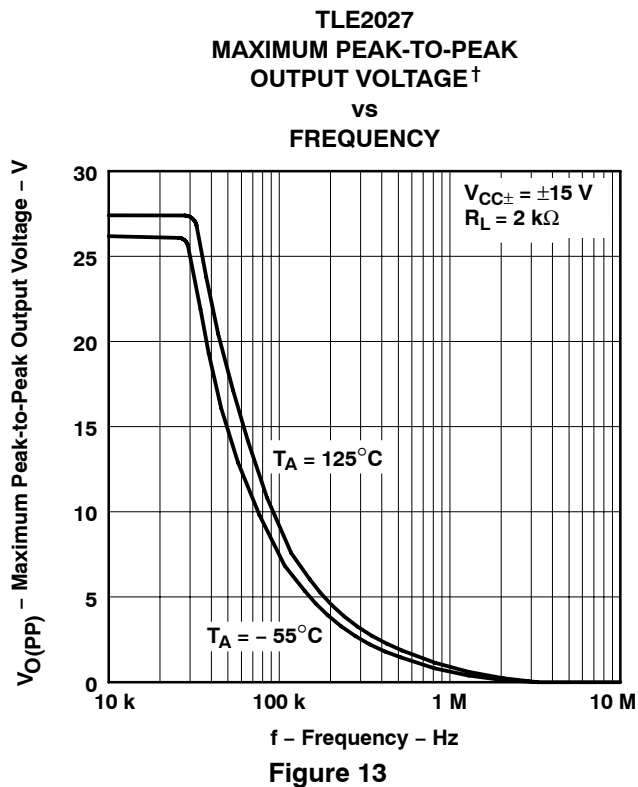
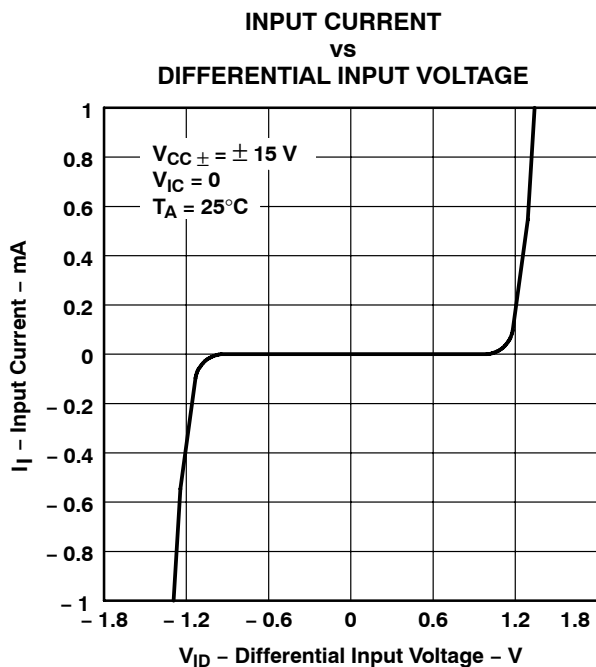
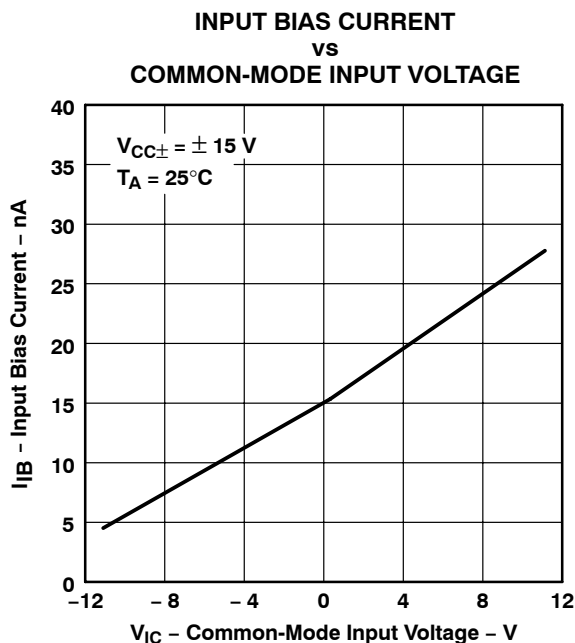
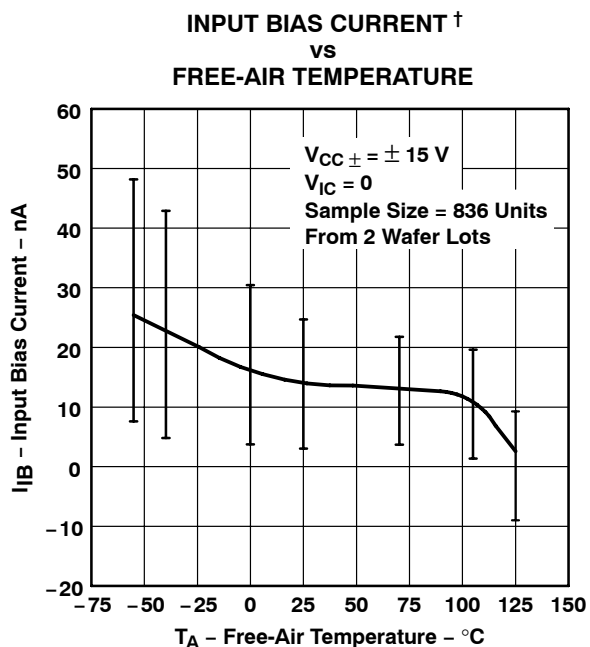
TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED

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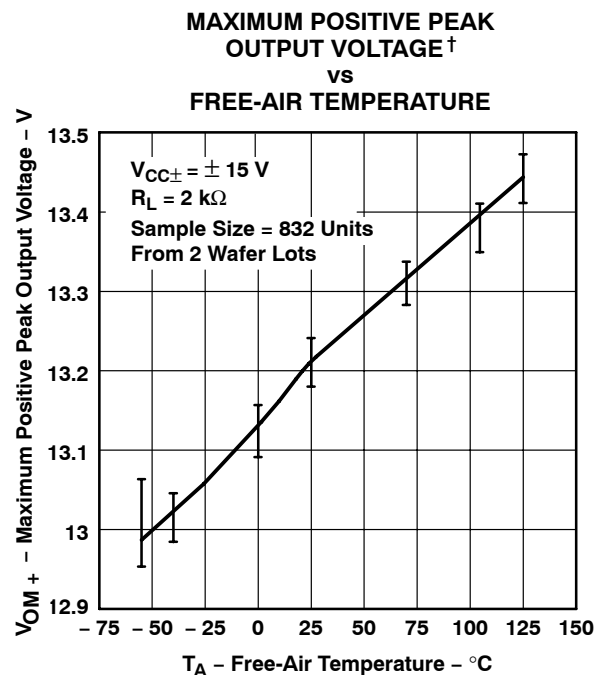
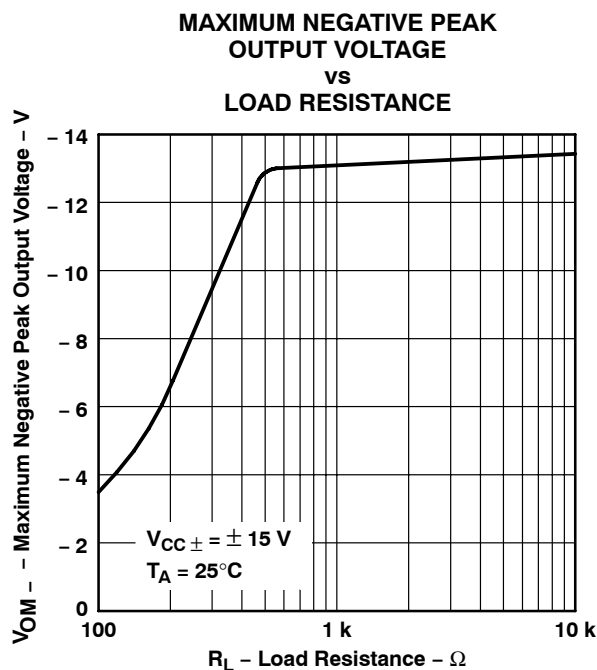
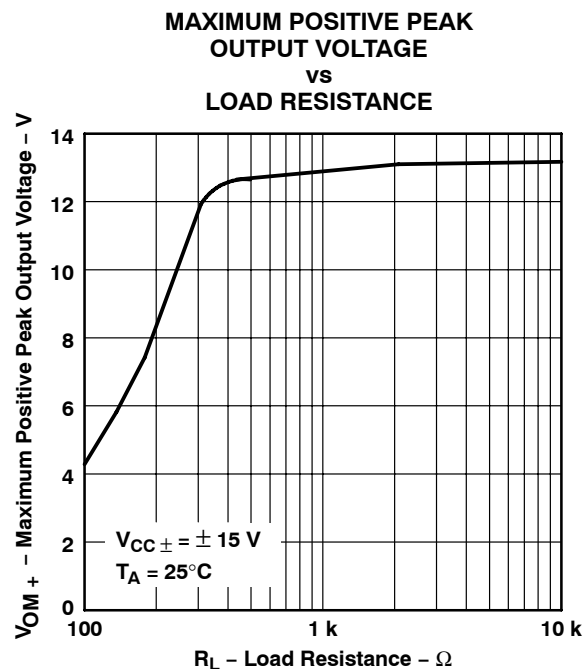
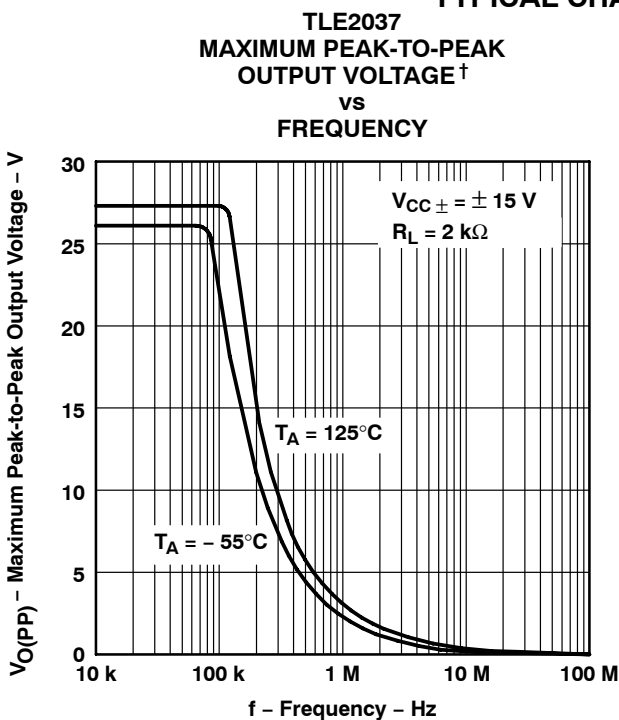
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TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED

PRECISION OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

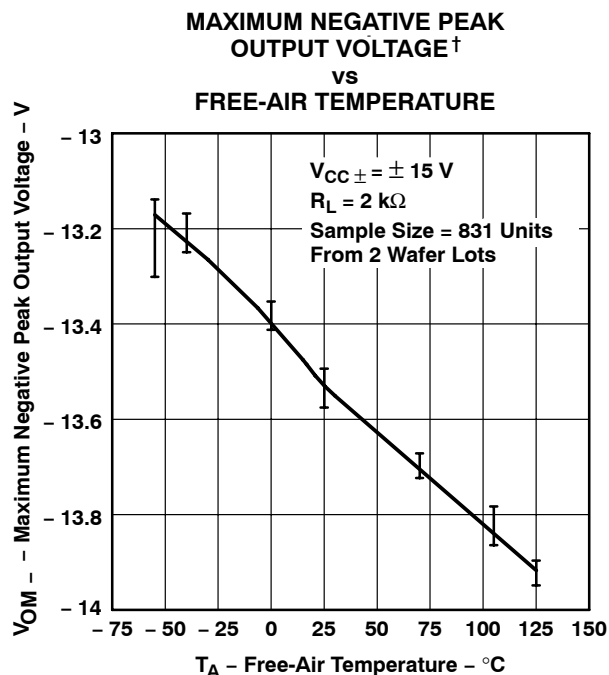


Figure 18

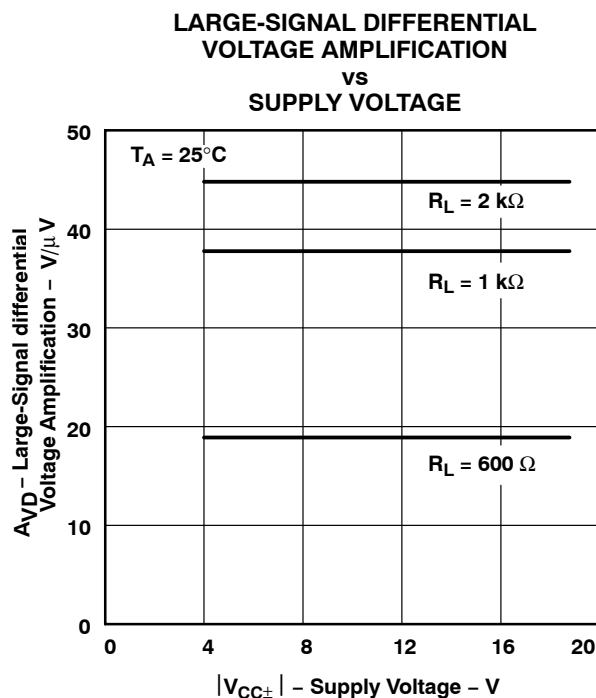


Figure 19

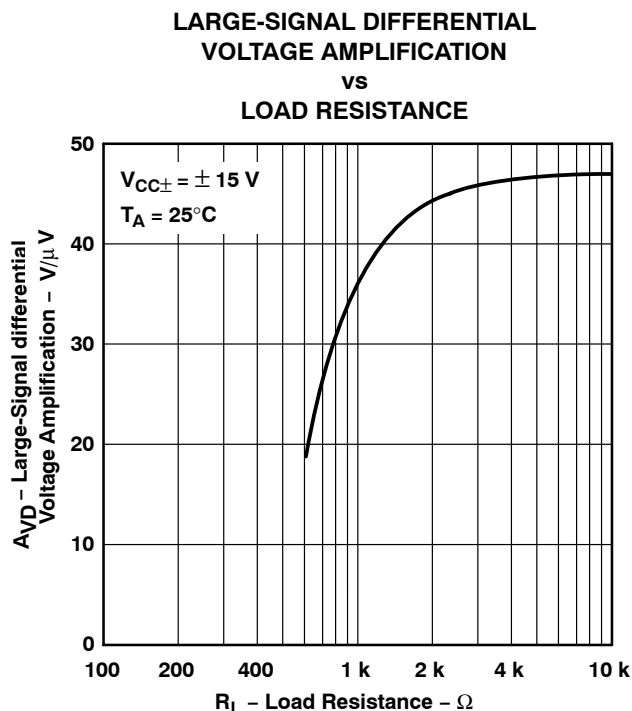


Figure 20

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

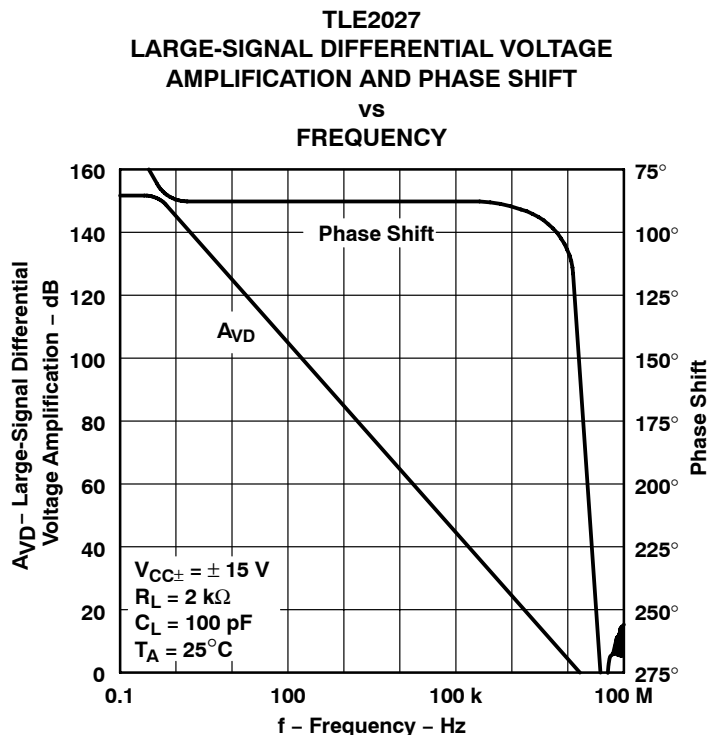


Figure 21

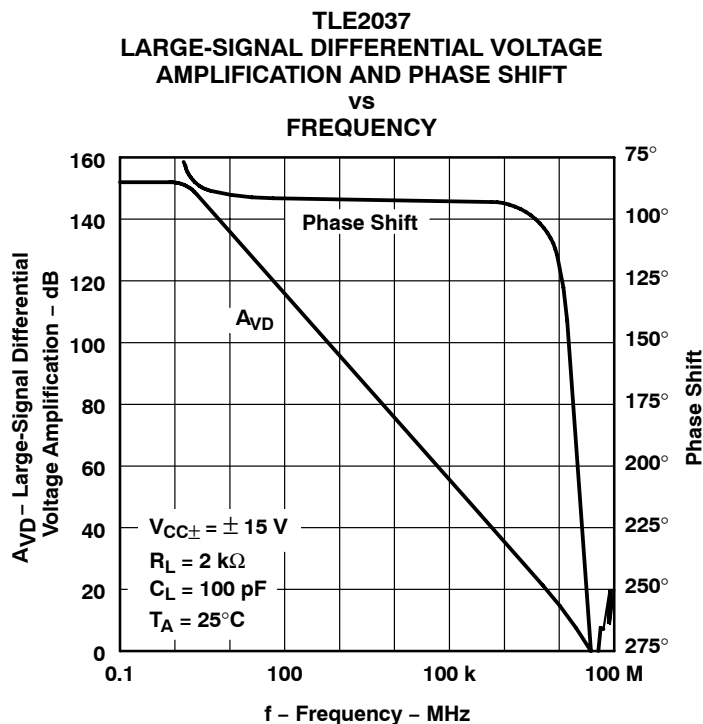


Figure 22

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

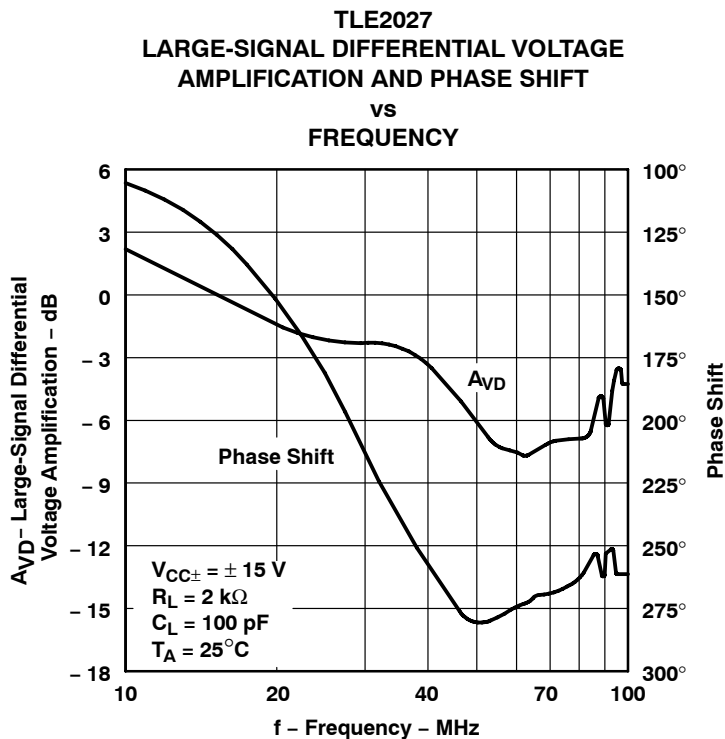


Figure 23

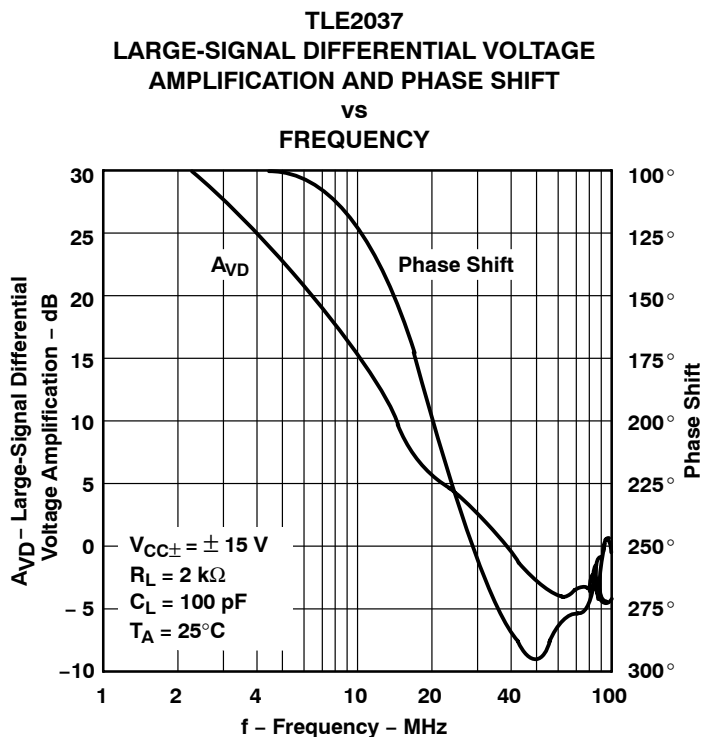


Figure 24

TYPICAL CHARACTERISTICS

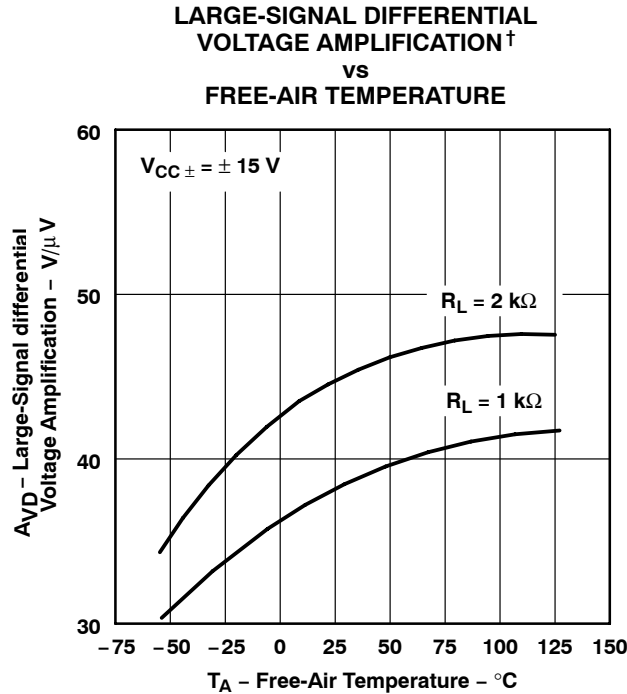
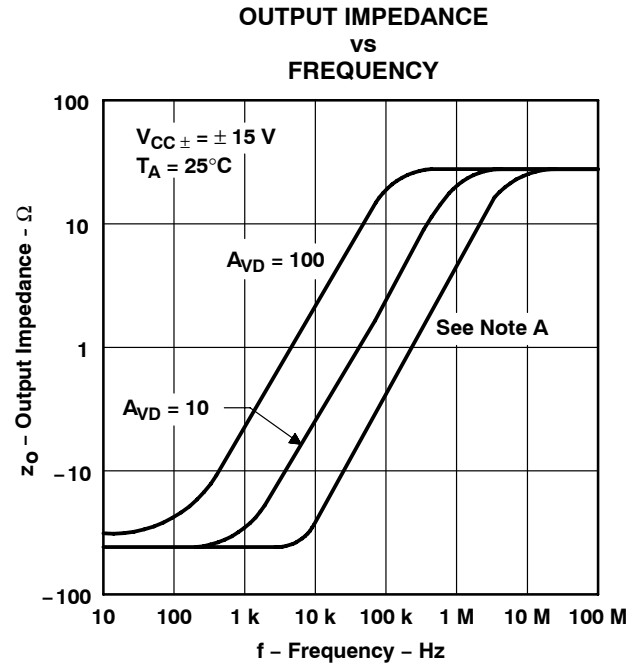


Figure 25



NOTE A: For this curve, the TLE2027 is $A_{VD} = 1$ and the TLE2037 is $A_{VD} = 5$.

Figure 26

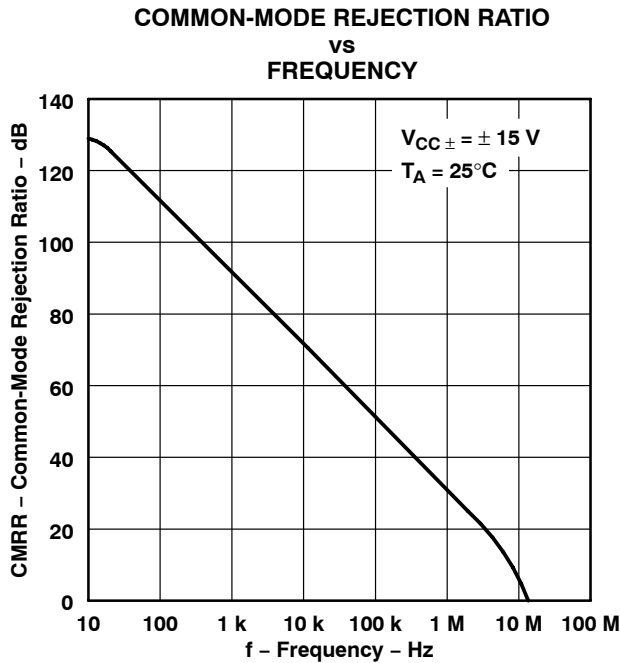


Figure 27

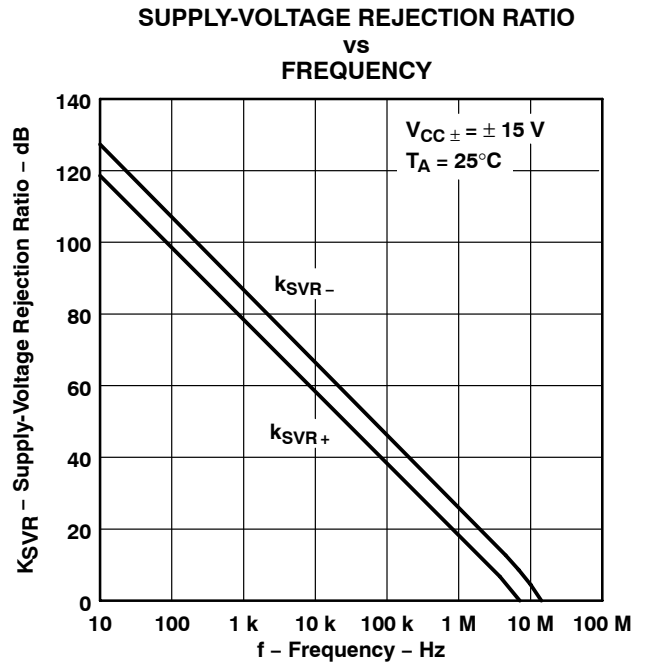


Figure 28

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

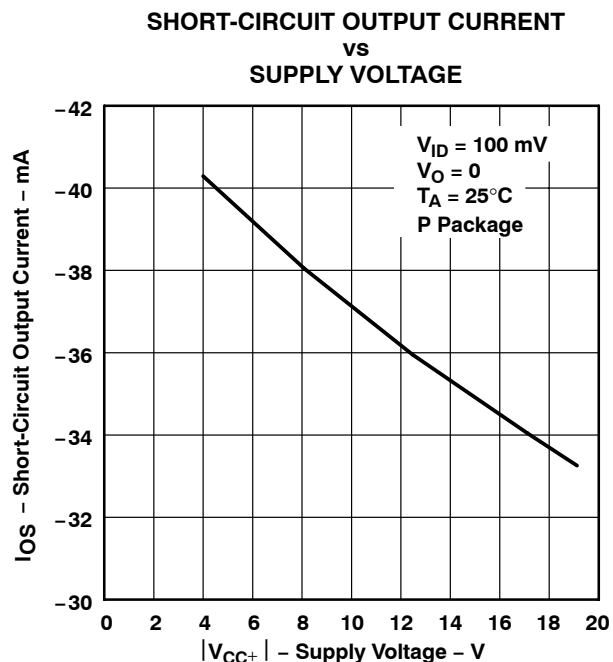


Figure 29

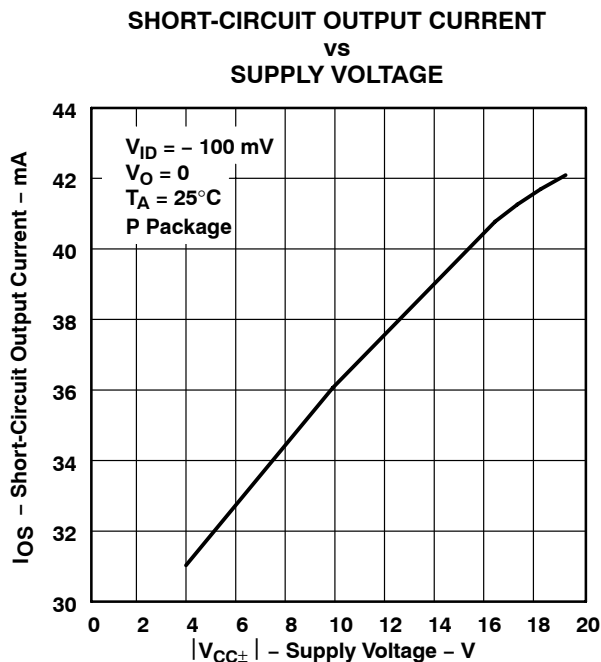


Figure 30

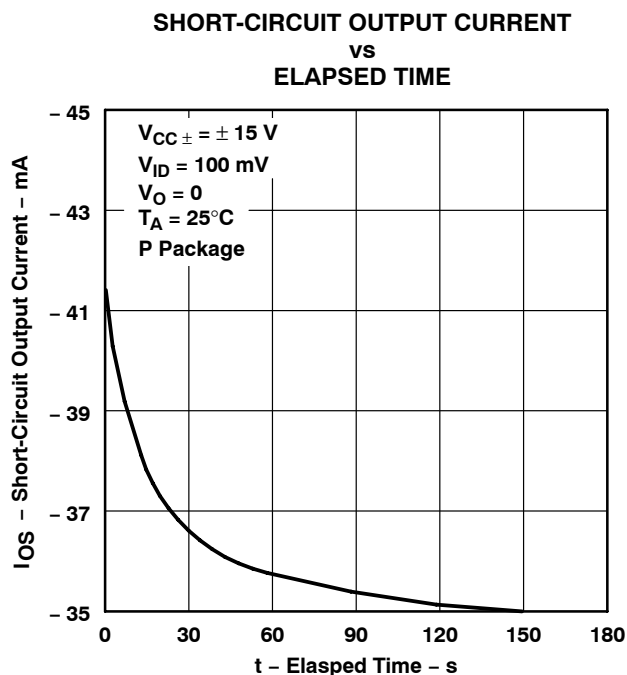


Figure 31

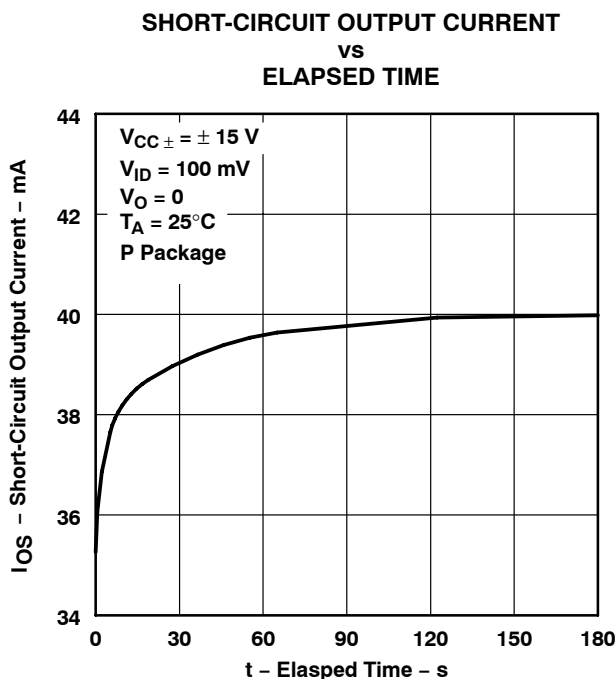


Figure 32

TYPICAL CHARACTERISTICS

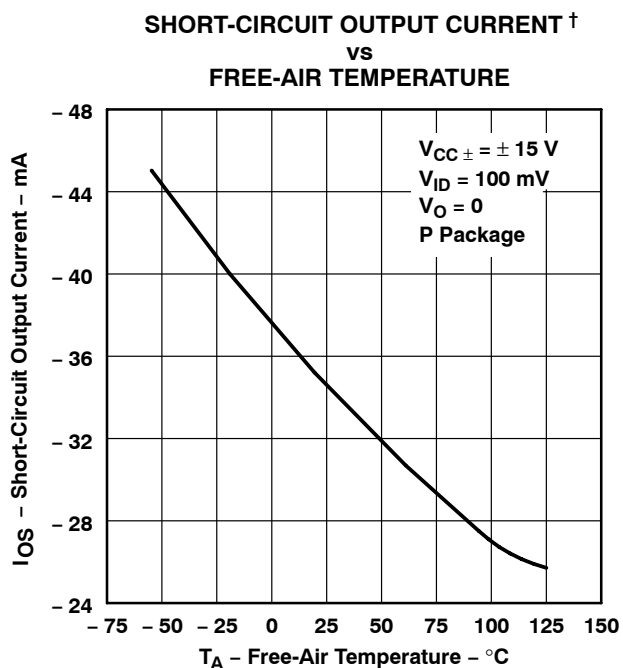


Figure 33

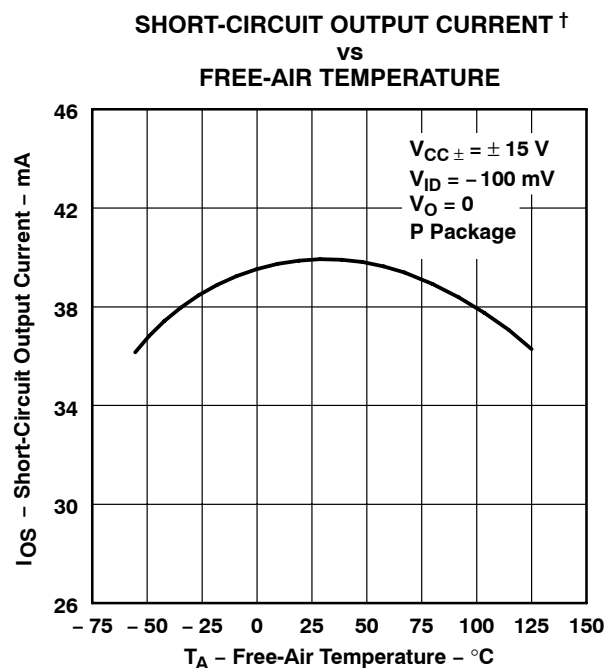


Figure 34

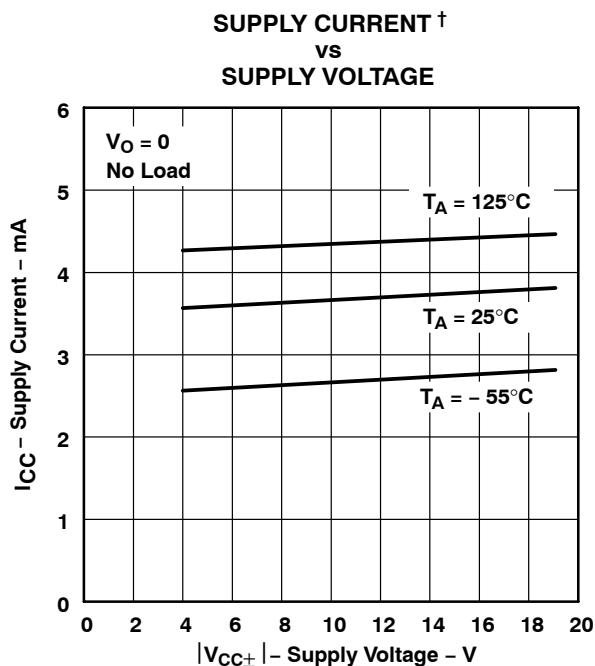


Figure 35

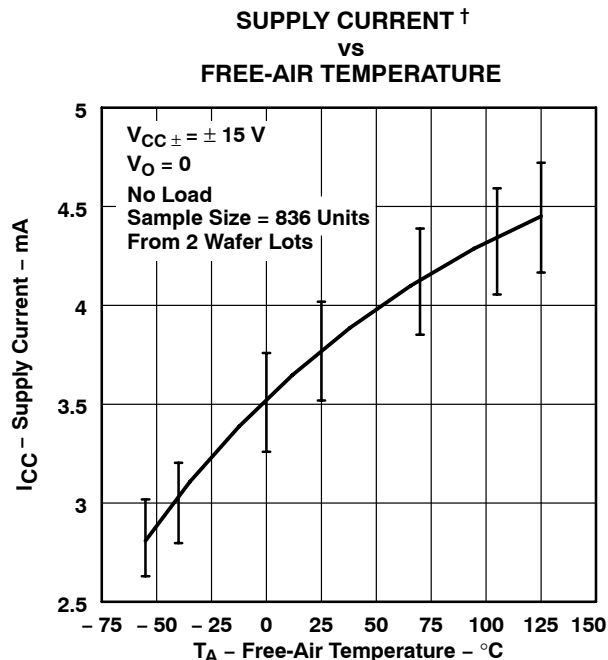


Figure 36

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

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TYPICAL CHARACTERISTICS

TLE2027
VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE

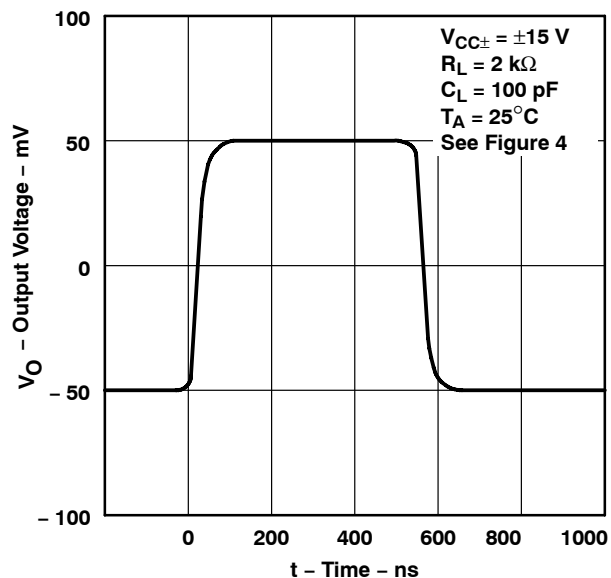


Figure 37

TLE2027
VOLTAGE-FOLLOWER
LARGE-SIGNAL
PULSE RESPONSE

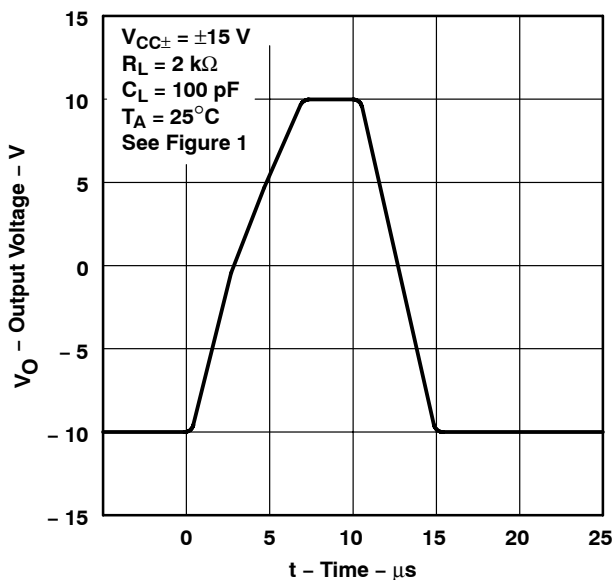


Figure 38

TLE2037
VOLTAGE-FOLLOWER
SMALL-SIGNAL
PULSE RESPONSE

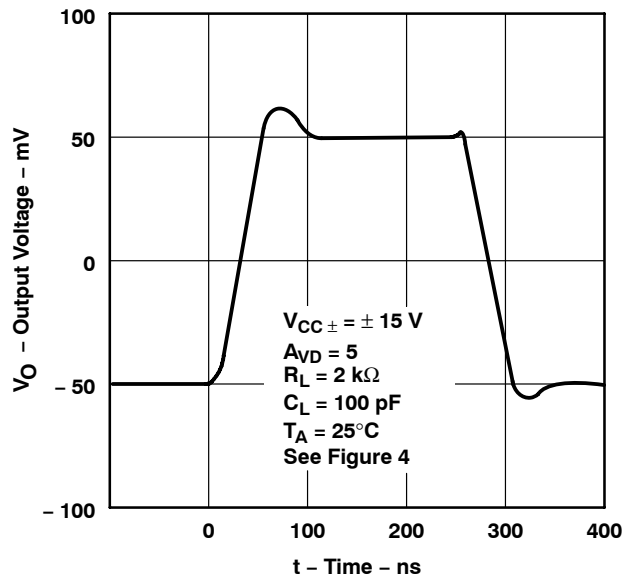


Figure 39

TLE2037
VOLTAGE-FOLLOWER
LARGE-SIGNAL
PULSE RESPONSE

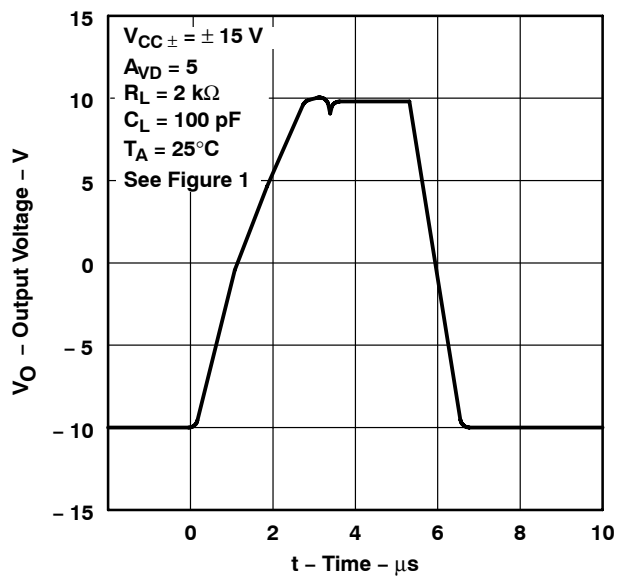


Figure 40

TYPICAL CHARACTERISTICS

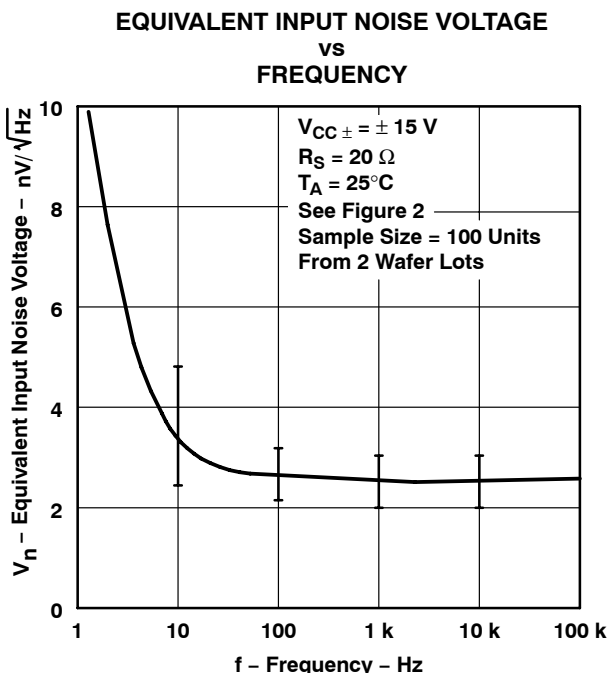


Figure 41

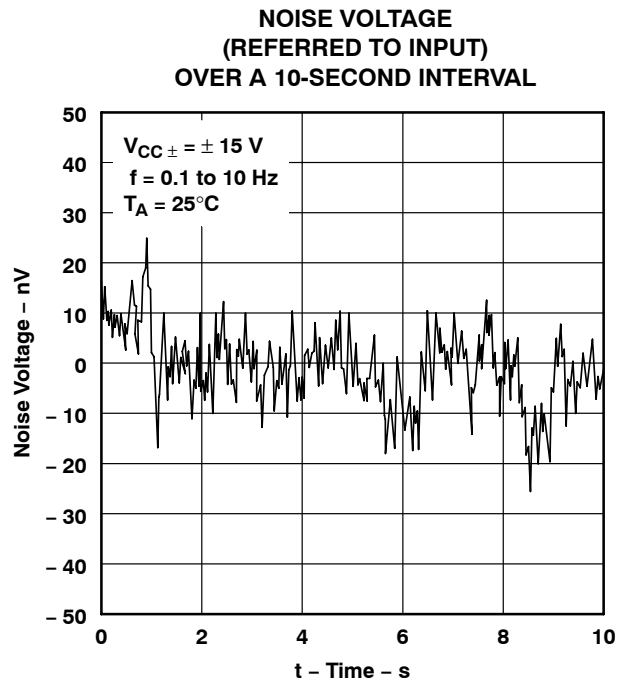


Figure 42

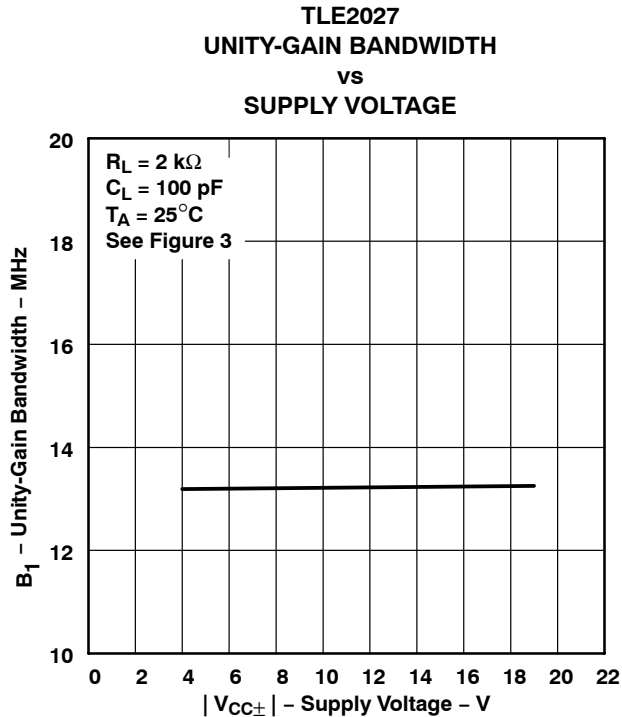


Figure 43

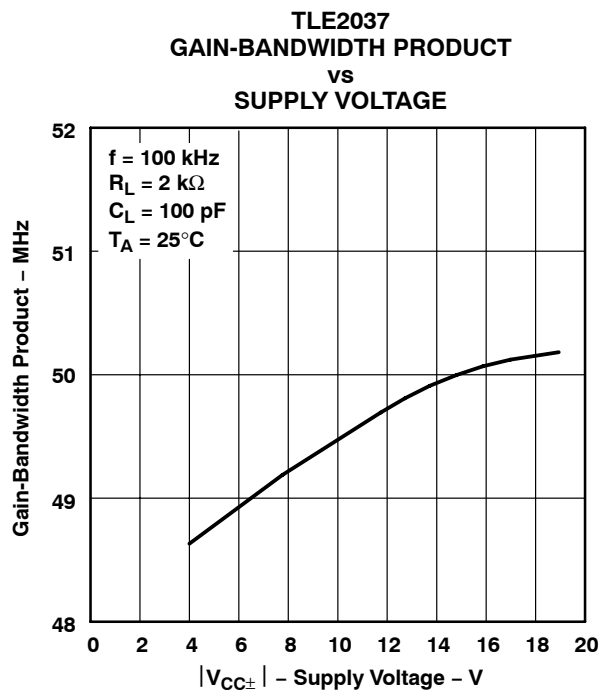


Figure 44

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED

PRECISION OPERATIONAL AMPLIFIERS

SLOS192C – FEBRUARY 1997 – REVISED APRIL 2010

TYPICAL CHARACTERISTICS

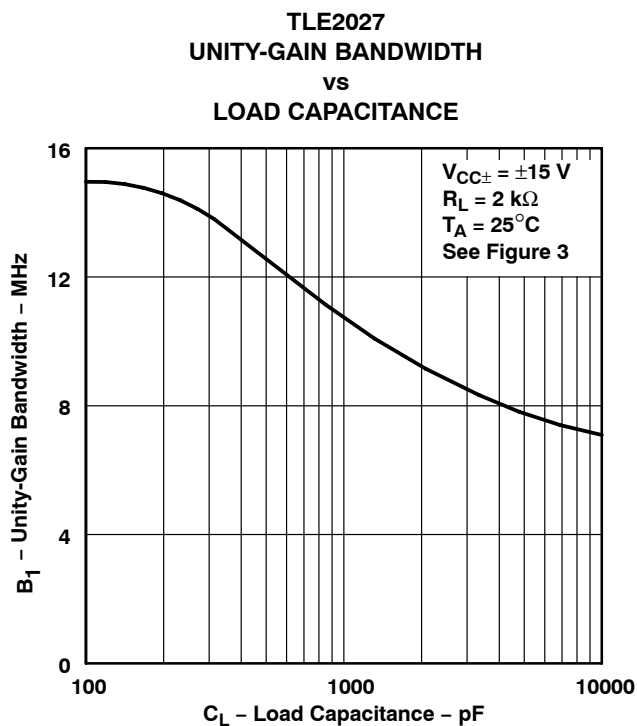


Figure 45

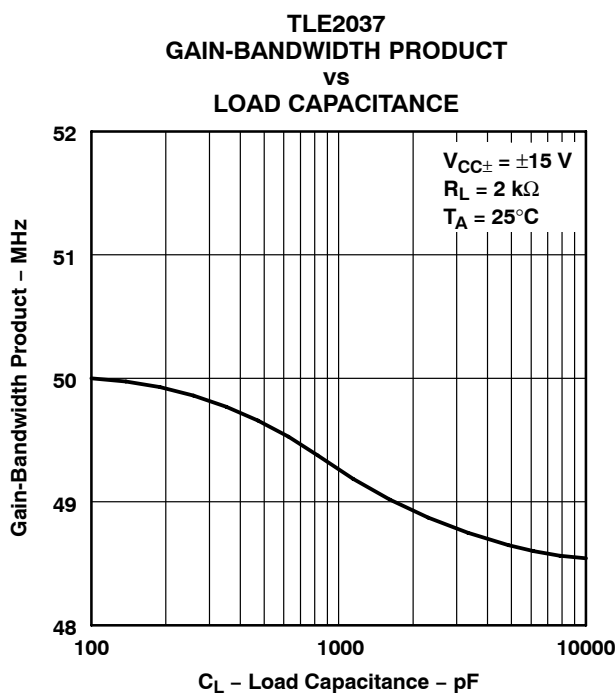


Figure 46

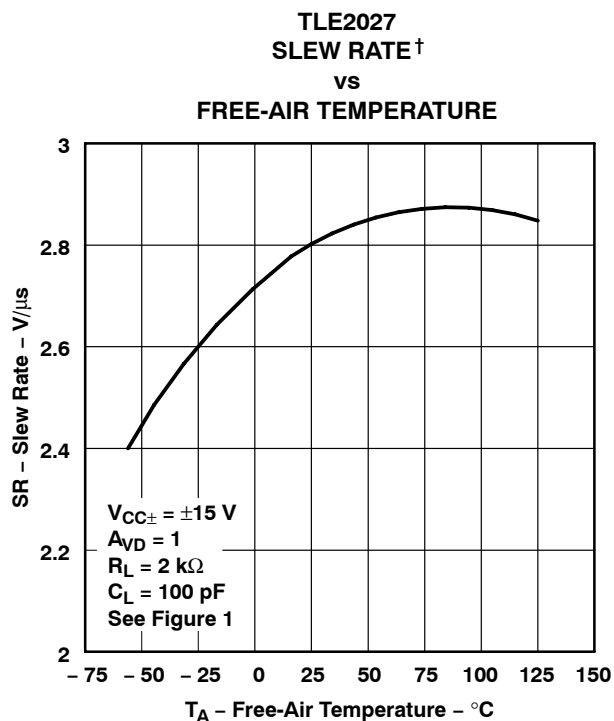


Figure 47

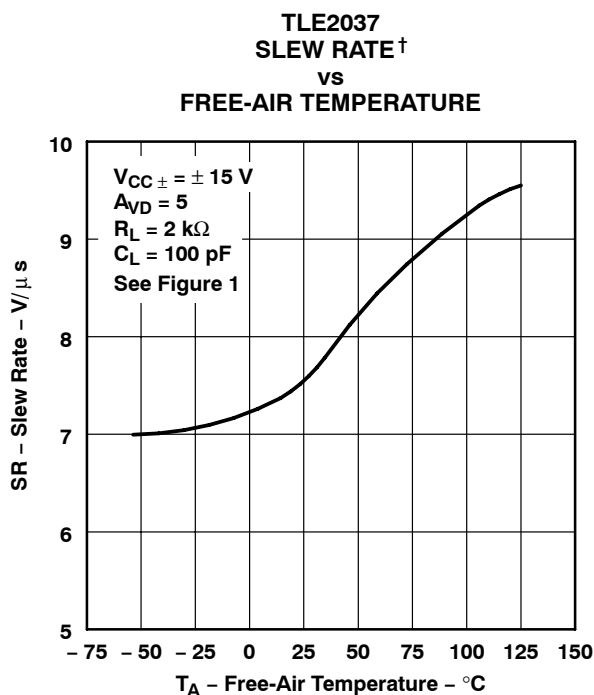


Figure 48

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

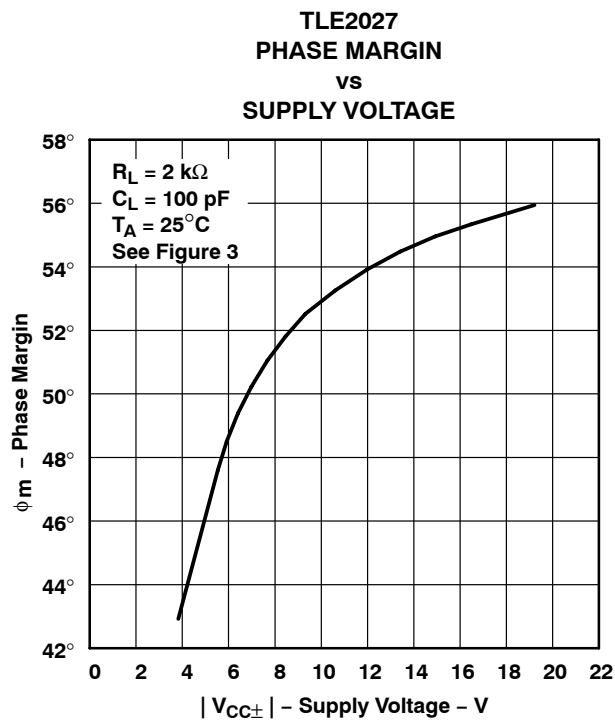


Figure 49

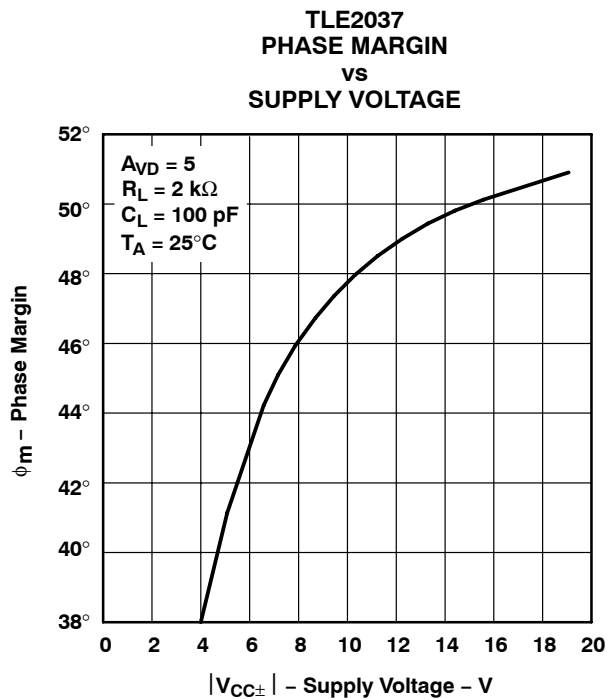


Figure 50

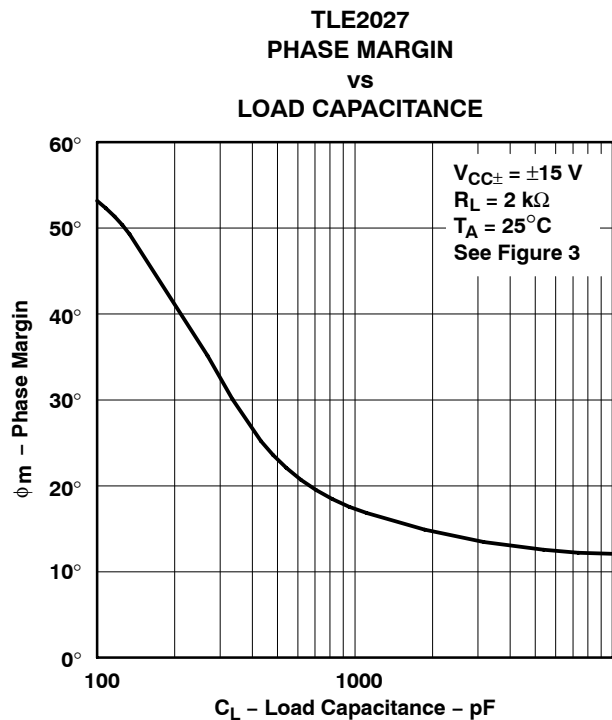


Figure 51

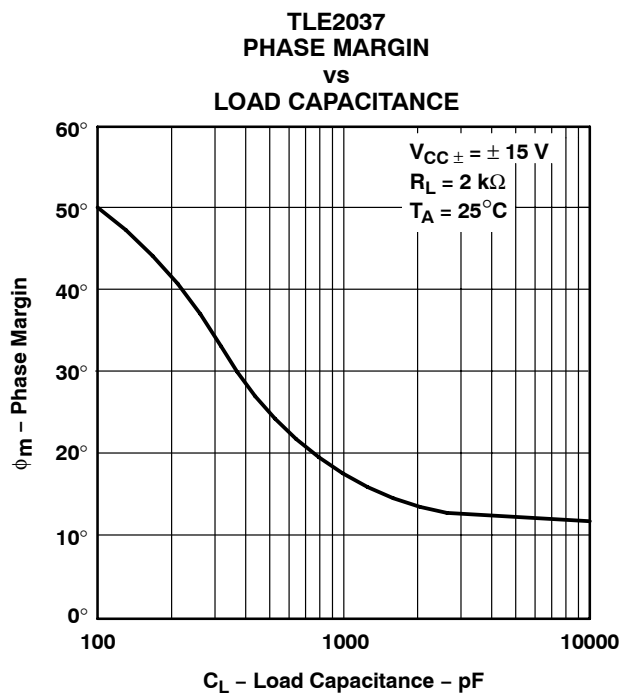


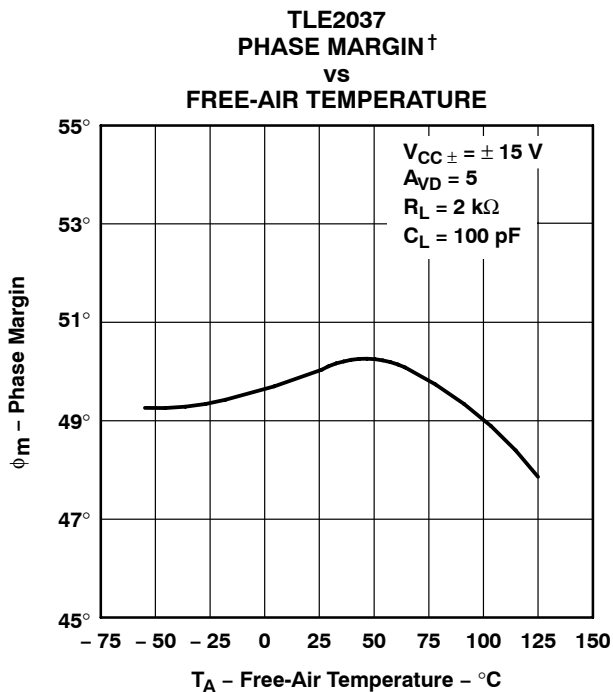
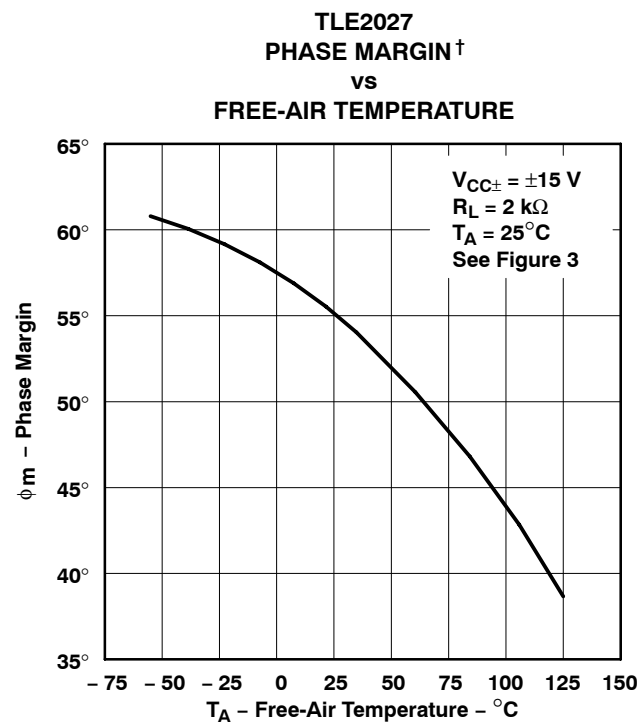
Figure 52

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y

EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

input offset voltage nulling

The TLE2027 and TLE2037 series offers external null pins that can be used to further reduce the input offset voltage. The circuits of Figure 55 can be connected as shown if the feature is desired. If external nulling is not needed, the null pins may be left disconnected.

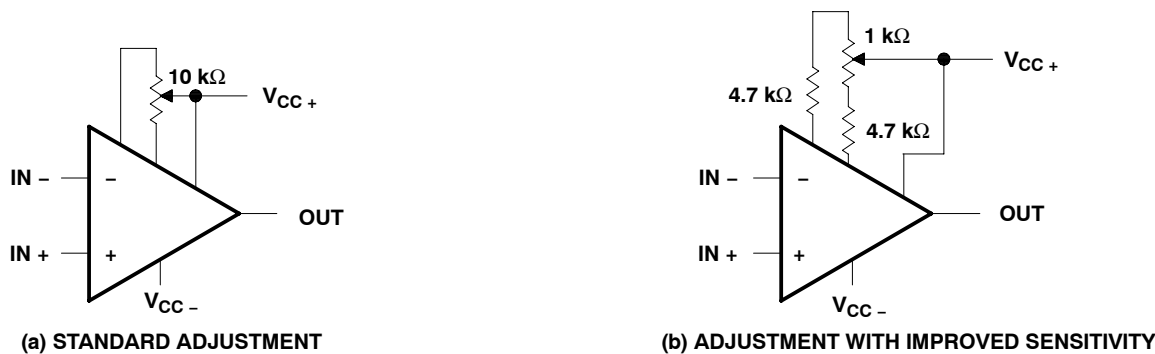


Figure 55. Input Offset Voltage Nulling Circuits

voltage-follower applications

The TLE2027 circuitry includes input-protection diodes to limit the voltage across the input transistors; however, no provision is made in the circuit to limit the current if these diodes are forward biased. This condition can occur when the device is operated in the voltage-follower configuration and driven with a fast, large-signal pulse. It is recommended that a feedback resistor be used to limit the current to a maximum of 1 mA to prevent degradation of the device. Also, this feedback resistor forms a pole with the input capacitance of the device. For feedback resistor values greater than 10 kΩ, this pole degrades the amplifier phase margin. This problem can be alleviated by adding a capacitor (20 pF to 50 pF) in parallel with the feedback resistor (see Figure 56).

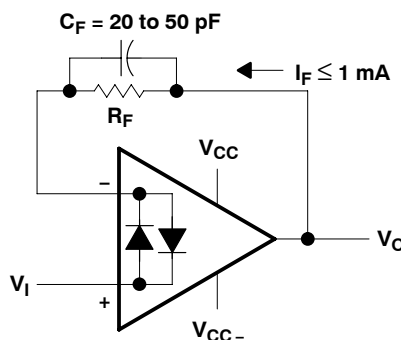


Figure 56. Voltage Follower

TLE2027, TLE2037, TLE2027A, TLE2037A, TLE2027Y, TLE2037Y EXCALIBUR LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIERS

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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 6) and subcircuit in Figure 57, Figure 58, and Figure 59 were generated using the TLE20x7 typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Gain-bandwidth product
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 6: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).

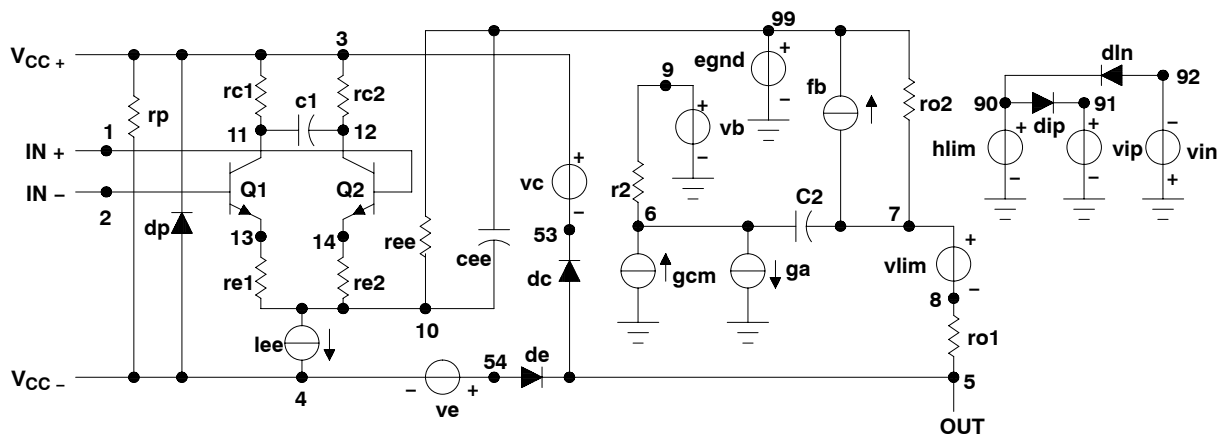


Figure 57. Boyle Macromodel

PSpice and *Parts* are trademarks of MicroSim Corporation.

APPLICATION INFORMATION

macromodel information (continued)

```
.subckt TLE2027 1 2 3 4 5
*
c1      11  12  4.003E-12
c2       6   7  20.00E-12
dc       5  53  dz
de      54   5  dz
dlp     90  91  dz
dln     92  90  dx
dp       4   3  dz
egnd    99   0  poly(2) (3,0)
(4,0) 0 5 .5
fb       7  99  poly(5) vb vc
ve vlp vln 0 954.8E6 -1E9 1E9 1E9
-1E9
ga       6   0  11  12
2.062E-3
gcm      0   6  10  99
531.3E-12
iee     10   4  dc 56.01E-6
hlim    90   0  vlim 1K
ql      11   2  13 qx

q2      12   1  14 qx
r2       6   9  100.0E3
rc1      3  11  530.5
rc2      3  12  530.5
re1     13  10 -393.2
re2     14  10 -393.2
ree     10  99  3.571E6
ro1      8   5  25
ro2      7  99  25
rp       3   4  8.013E3
vb       9   0  dc 0
vc       3  53  dc 2.400
ve      54   4  dc 2.100
vlim     7   8  dc 0
vlp     91   0  dc 40
vln      0  92  dc 40
.modeldx D(Is=800.0E-18)
.modelqx NPN(Is=800.0E-18
Bf=7.000E3)
.ends
```

Figure 58. TLE2027 Macromodel Subcircuit

```
.subckt TLE2037 1 2 3 4 5
*
c1      11  12  4.003E-12
c2       6   7  7.500E-12
dc       5  53  dz
de      54   5  dz
dlp     90  91  dz
dln     92  90  dx
dp       4   3  dz
egnd    99   0  poly(2) (3,0)
(4,0) 0 .5 .5
fb       7  99  poly(5) vb vc
ve vip vln 0 923.4E6 A800E6
800E6 800E6 A800E6
ga       6   0  11  12 2.121E-3
gcm      0   6  10  99 597.7E-12
iee     10   4  dc 56.26E-6
hlim    90   0  vlim 1K
ql      11   2  13 qx

q2      12   1  14 qz
r2       6   9  100.0E3
rc1      3  11  471.5
rc2      3  12  471.5
re1     13  10 A448
re2     14  10 A448
ree     10  99  3.555E6
ro1      8   5  25
ro2      7  99  25
rp       3   4  8.013E3
vb       9   0  dc 0
vc       3  53  dc 2.400
ve      54   4  dc 2.100
vlim     7   8  dc 0
vlp     91   0  dc 40
vln      0  92  dc 40
.model   dxD(Is=800.0E-18)
.model   qxNPN(Is=800.0E-18
Bf=7.031E3)
.ends
```

Figure 59. TLE2037 Macromodel Subcircuit

REVISION HISTORY

Changes from Revision B (October 2006) to Revision C

- Changed values of V_n , $V_{N(PP)}$, and I_n 11

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9089601M2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9089601M2A TLE2027MFKB	Samples
5962-9089601MPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9089601MPA TLE2027M	Samples
5962-9089603Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9089603Q2A TLE2027AMFKB	Samples
5962-9089603QPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9089603QPA TLE2027AM	Samples
TLE2027AMD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2027AM	Samples
TLE2027AMFKB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9089603Q2A TLE2027AMFKB	Samples
TLE2027AMJG	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	TLE2027 AMJG	Samples
TLE2027AMJGB	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9089603QPA TLE2027AM	Samples
TLE2027CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2027C	Samples
TLE2027CDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2027C	Samples
TLE2027CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2027C	Samples
TLE2027ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2027I	Samples
TLE2027IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2027I	Samples
TLE2027MD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2027M	Samples
TLE2027MFKB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9089601M2A TLE2027MFKB	Samples
TLE2027MJGB	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9089601MPA TLE2027M	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2037AMD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2037AM	Samples
TLE2037AMDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2037AM	Samples
TLE2037CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037C	Samples
TLE2037CDG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037C	Samples
TLE2037CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037C	Samples
TLE2037ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037I	Samples
TLE2037IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037I	Samples
TLE2037IDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		2037I	Samples
TLE2037MD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2037M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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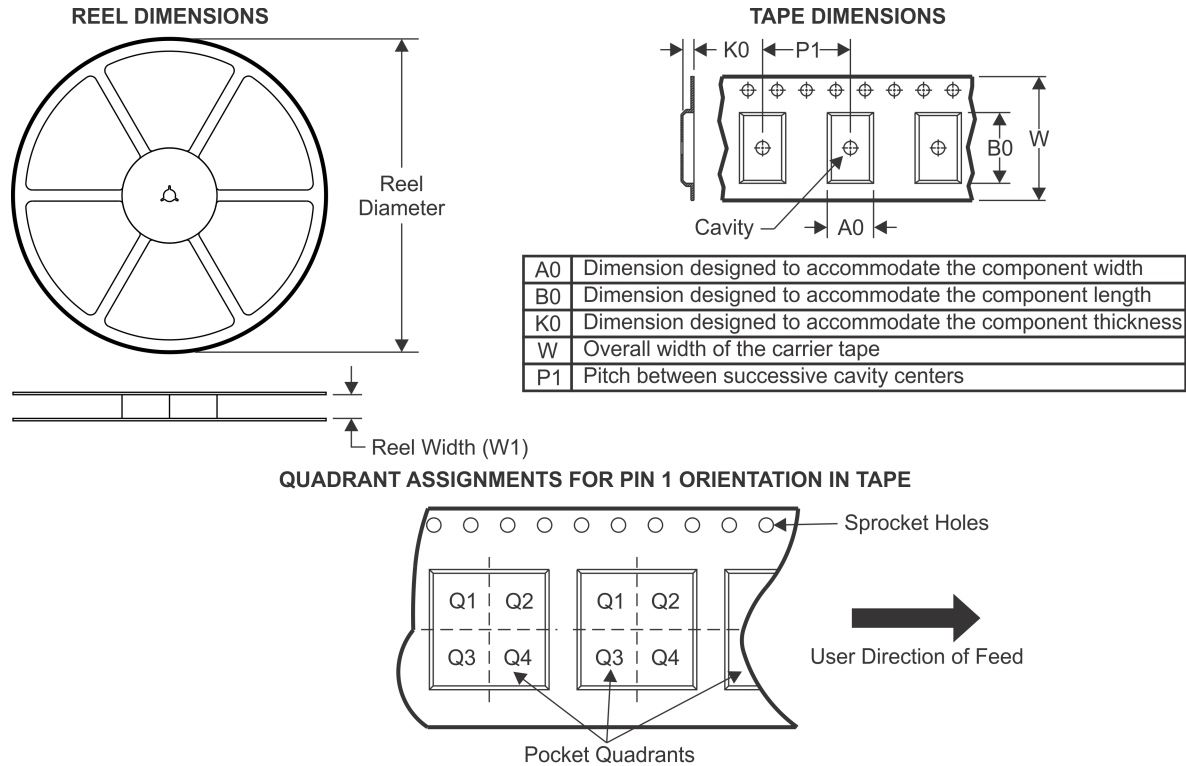
OTHER QUALIFIED VERSIONS OF TLE2027, TLE2027M, TLE2037A :

- Catalog : [TLE2027](#)
- Automotive : [TLE2037A-Q1](#)
- Enhanced Product : [TLE2027-EP](#) , [TLE2027-EP](#)
- Military : [TLE2027M](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

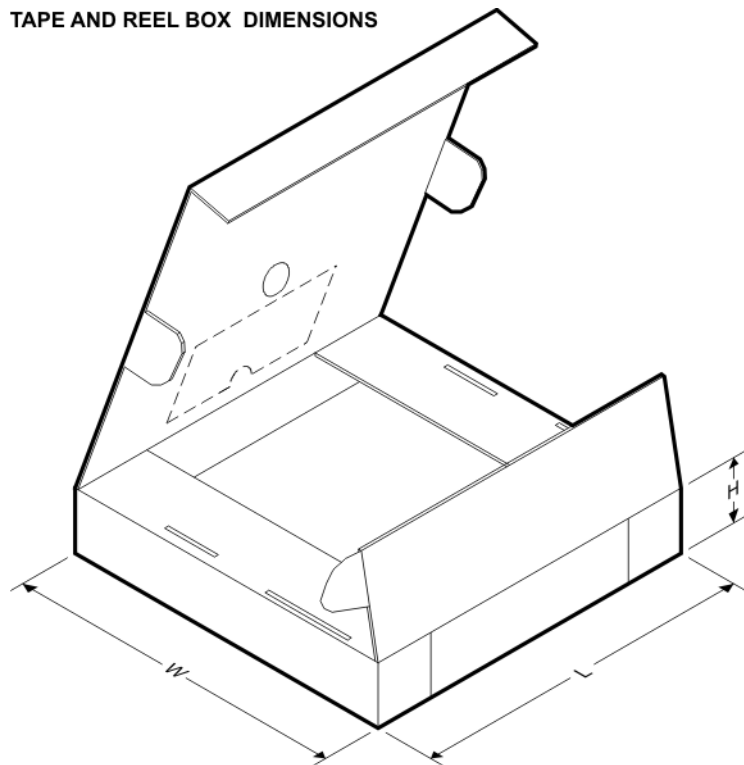
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2027CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2027IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2037CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2037IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

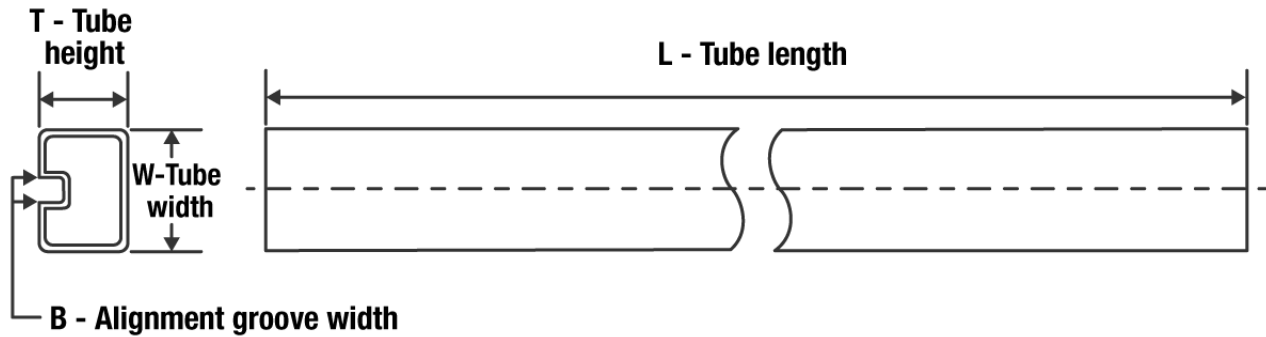
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2027CDR	SOIC	D	8	2500	340.5	336.1	25.0
TLE2027IDR	SOIC	D	8	2500	340.5	336.1	25.0
TLE2037CDR	SOIC	D	8	2500	340.5	336.1	25.0
TLE2037IDR	SOIC	D	8	2500	340.5	336.1	25.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9089601M2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9089603Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
TLE2027AMD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2027AMFKB	FK	LCCC	20	1	506.98	12.06	2030	NA
TLE2027CD	D	SOIC	8	75	507	8	3940	4.32
TLE2027CD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2027CDG4	D	SOIC	8	75	505.46	6.76	3810	4
TLE2027CDG4	D	SOIC	8	75	507	8	3940	4.32
TLE2027ID	D	SOIC	8	75	507	8	3940	4.32
TLE2027ID	D	SOIC	8	75	505.46	6.76	3810	4
TLE2027MD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2027MFKB	FK	LCCC	20	1	506.98	12.06	2030	NA
TLE2037AMD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2037AMDG4	D	SOIC	8	75	505.46	6.76	3810	4
TLE2037CD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2037CD	D	SOIC	8	75	507	8	3940	4.32
TLE2037CDG4	D	SOIC	8	75	505.46	6.76	3810	4
TLE2037CDG4	D	SOIC	8	75	507	8	3940	4.32
TLE2037ID	D	SOIC	8	75	507	8	3940	4.32
TLE2037ID	D	SOIC	8	75	505.46	6.76	3810	4
TLE2037MD	D	SOIC	8	75	505.46	6.76	3810	4



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



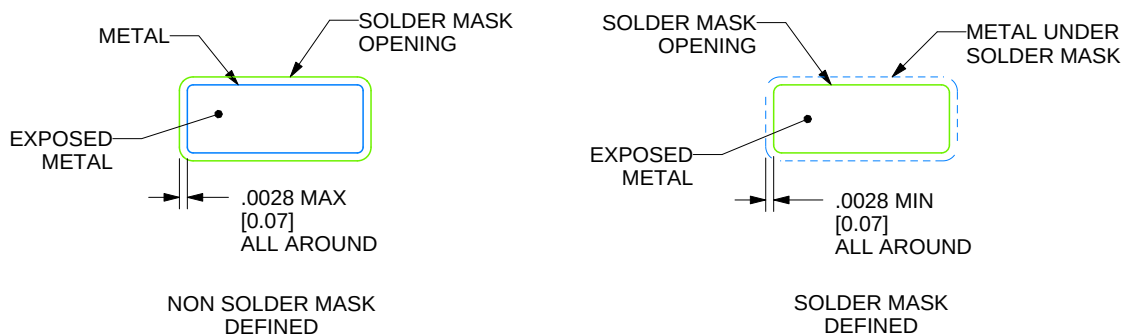
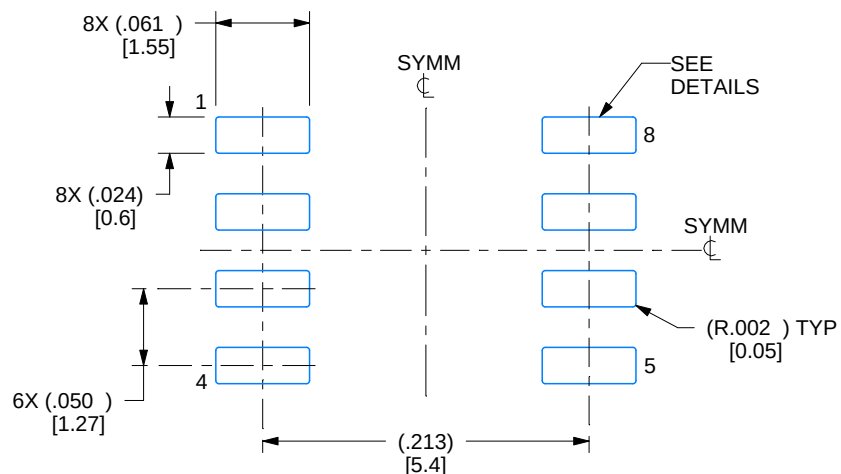
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

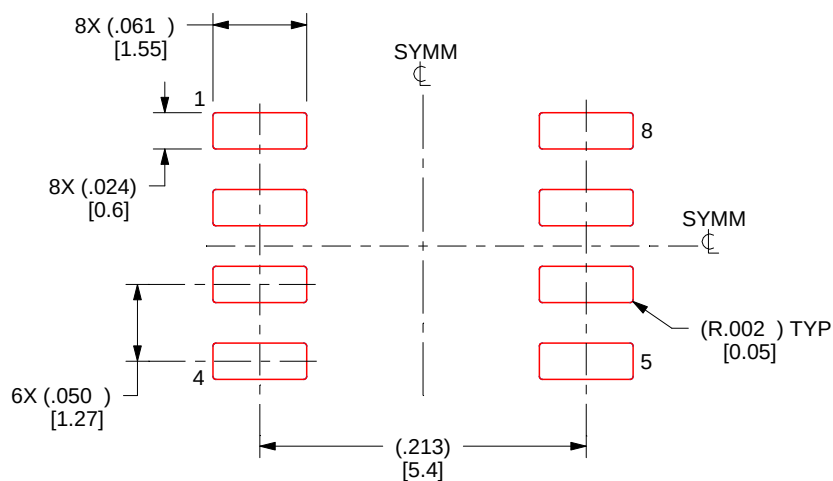
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

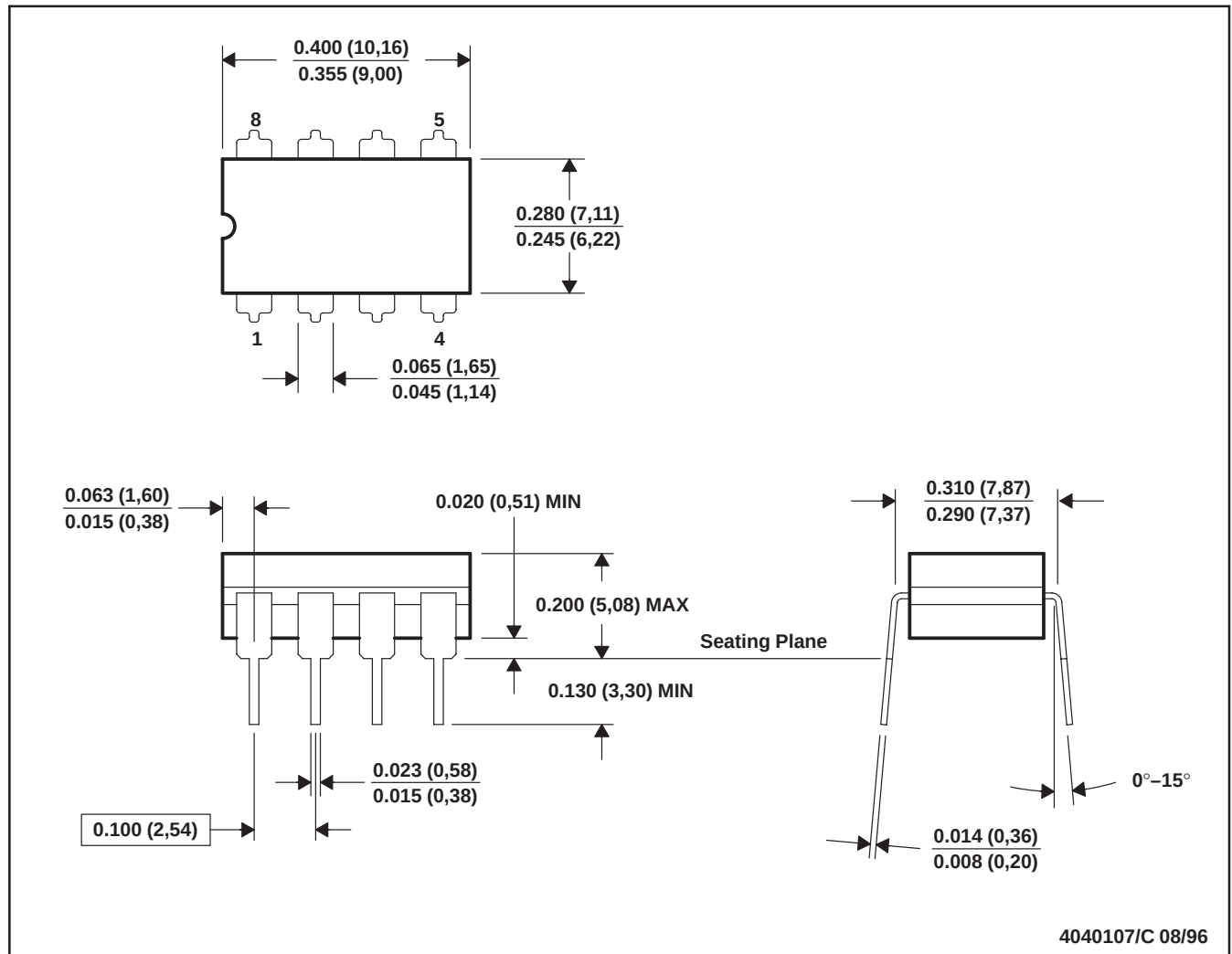
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

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